

FEATURES

- Operation Voltage: 6.3V ~ 24V power supply.
- Standby current(I_{sb}) :
Typical 30uA at 8.4V/shutdown mode. (no load) °
- Quiescent current :
Typical 20mA at 12V/with Mute mode (no load) °
- Differential or Single-end inputs °
- 4 kinds of output type options:
4xSE、2xBTL、2.1CH、1xPBTL mode °
- High output power capability:
(Test @1KHz,THD+N=10%,25°C)

R _{Load}		4Ω		8Ω	
Output	Vol.	1%	10%	1%	10%
SEx4	12V	3.5W	4.5W	2W	2.5W
	19V	9W	10W	5W	6W
	24V	14W ^{*3}	18W ^{*3}	8W	10W
BTLx2	7.4V	5W	6W	2.5W	3.5W
	8.4V	6.5W	8W	3.5W	4.5W
	12V	13W	16W	7.5W	9W
	16V	24W ^{*3}	29W ^{*3}	14W	17W
	19V	33W ^{*3}	40W ^{*3}	19W ^{*3}	22W ^{*3}

R _{Load}		2Ω		4Ω	
Output	Vol.	1%	10%	1%	10%
PBTLx1	7.4V	9W	11W	5W	6W
	8.4V	13W	16W	7.5W	9W
	12V	25W	30W	16W	19W
	16V	-	-	29W ^{*3}	33W ^{*3}
	19V	-	-	39W ^{*3}	47W ^{*3}

- Short-Circuit protection with automatic recovery.
Pin to pin and pin to PVDD&GND
- Over-Heat protection with automatic recovery.
Shutdown temp:160°C/Restore temp:110°C °
- Under(6V) and Over(30V) voltage detection.
- FAULT pin function.
- L/C filter-free operation
(Except for single-ended output mode .)
- Mute function selectable.
- Power ON/OFF pop reduction.
- Digital gain selection.(20/26/32/36 db)
- 28-pin TSSOP 173mil package with thermal pad.

GENERAL DESCRIPTION

The LY8326A is a high efficiency class D audio power amplifier. It can to work either in dual bridge、quad single-ended output、2.1 channel and PBTL mono application configuration. The device use advanced EMI suppression technology enables the use low cost ferrite-bead filters at the outputs while meeting EMC requirements. The outputs are also fully protected against short to PVDD or GND or output-to-output pin. The short-circuit protection and thermal protection include an auto-recovery feature. The device features a low noise and a low power consumption in shutdown mode. It also utilizes circuitry to reduce low noise during device turn-on.

APPLICATION

- Sound-bar Home Theater.
- Powered Speakers.
- Music instrument devices.
- Multimedia TFT LCD Monitors.

PIN CONFIGURATION

LY8326A TSSOP28 pin configuration (TOP VIEW)

1	SDB	BSTPL	28
2	FAULTB	OUTPL	27
3	GAIN0	PVCC	26
4	GAIN1	BSTNL	25
5	LINP	OUTNL	24
6	LINN	PAGND	23
7	BYPASS	PAGND	22
8	AGND	PAGND	21
9	RINN	OUTNR	20
10	RINP	BSTNR	19
11	MUTE	PVCC	18
12	MODE	OUTPR	17
13	GVDD	BSTPR	16
14	NC	AVCC	15



PIN DESCRIPTION

SYMBOL	Pin No.	DESCRIPTION
SDB	1	Shutdown control pin.(when LOW level in shutdown mode).
FAULTB	2	Open drain output used to display short circuit status. Voltage compliant to GVDD. Short circuit faults can be set to auto-recovery by connecting FAULT pin to SD pin. Short circuit faults must be reset by cycling PVCC or MCU.
GAIN0	3	Gain select pin.
GAIN1	4	Gain select pin.
LINP	5	Positive(+) L channel audio input.
LINN	6	Negative(-) L channel audio input.
BYPASS	7	Bypass pin.
AGND	8	Analog GND.
RINN	9	Negative(-) R channel audio input.
RINP	10	Positive(+) R channel audio input.
MUTE	11	Mute signal for quick enable/disable of output. ((When HIGH (connect to GVDD) level in mute mode).
MODE	12	Output mode selectable.
GVDD	13	High-side FET gate drive supply. Nominal voltage is 6.9V.
NC	14	
AVCC	15	Analog Power supply.
BSTPR	16	Bootstrap I/O for Positive(+) R channel.
OUTPR	17	Speaker output for Positive(+) R channel.
PVCC	18/26	Power supply of R \ L channel.
BSTNR	19	Bootstrap I/O for Negative(-) R channel.
OUTNR	20	Speaker output for Negative(-) R channel.
PGND	21/22/23	Ground of R \ L channel.
OUTNL	24	Speaker output for Negative(-) L channel.
BSTNL	25	Bootstrap I/O for Negative(-) L channel.
OUTPL	27	Speaker output for Positive(+) L channel.
BSTPL	28	Bootstrap I/O for Positive(+) L channel.
Thermal Pad		Must be soldered to PCB's ground plane.



ORDERING INFORMATION

Ordering Code	Speaker Channels	Pin/ Package	Output Power (THD+N=10%) ^(*3)		Input Type	Output Type	
			R _{Load}				
LY8326A	Multi channel	TSSOP28	R _{Load}	<u>4Ω</u>	<u>8Ω</u>	Single-End / Differential	SEx4 ^(*4) 2xBTL 2.1CH 1xPBTL
			SEx4	4.5Wx4/12V	6Wx4/19V		
				10Wx4/19V	10Wx4/24V		
			BTLx2	6Wx2/7.4V	3.5Wx2/7.4V		
				8Wx2/8.4V	4.5Wx2/8.4V		
				16Wx2/12V	9Wx2/12V		
				20Wx2/19V ^{*5}	22Wx2/19V ^{*5}		
			2.1CH	6Wx2+20Wx1 /14V	6Wx2+22Wx1 /19V		
R _{Load}	<u>2Ω</u>	<u>4Ω</u>					
PBTLx1	30Wx1/12V	40Wx1/19V					

(*3) The device must be mounted to the PCB board and increase a large area of copper or recommended to use external heat sink. For best performance, when driving $\leq 12V/4\Omega$ power and loading.

(*4) If Output type select SEx4, The audio input must use Single-End type.

(*5) Must use external heat sink.

DEMO BOARD ORDERING INFORMATION

Demo Board Ordering Code	Pin/ Package	Input Type	Speaker Output Channels	Notes
LY8326A-DB1	TSSOP28	Single-End / Differential	PBTL mode (Mono)	
LY8326A-DB2			BTLx2 mode (Stereo)	
LY8326A-DB3			2.1CH mode (SEx2+BTLx1)	
LY8326A-DB4			SEx4 mode	

TYPICAL APPLICATION CIRCUIT

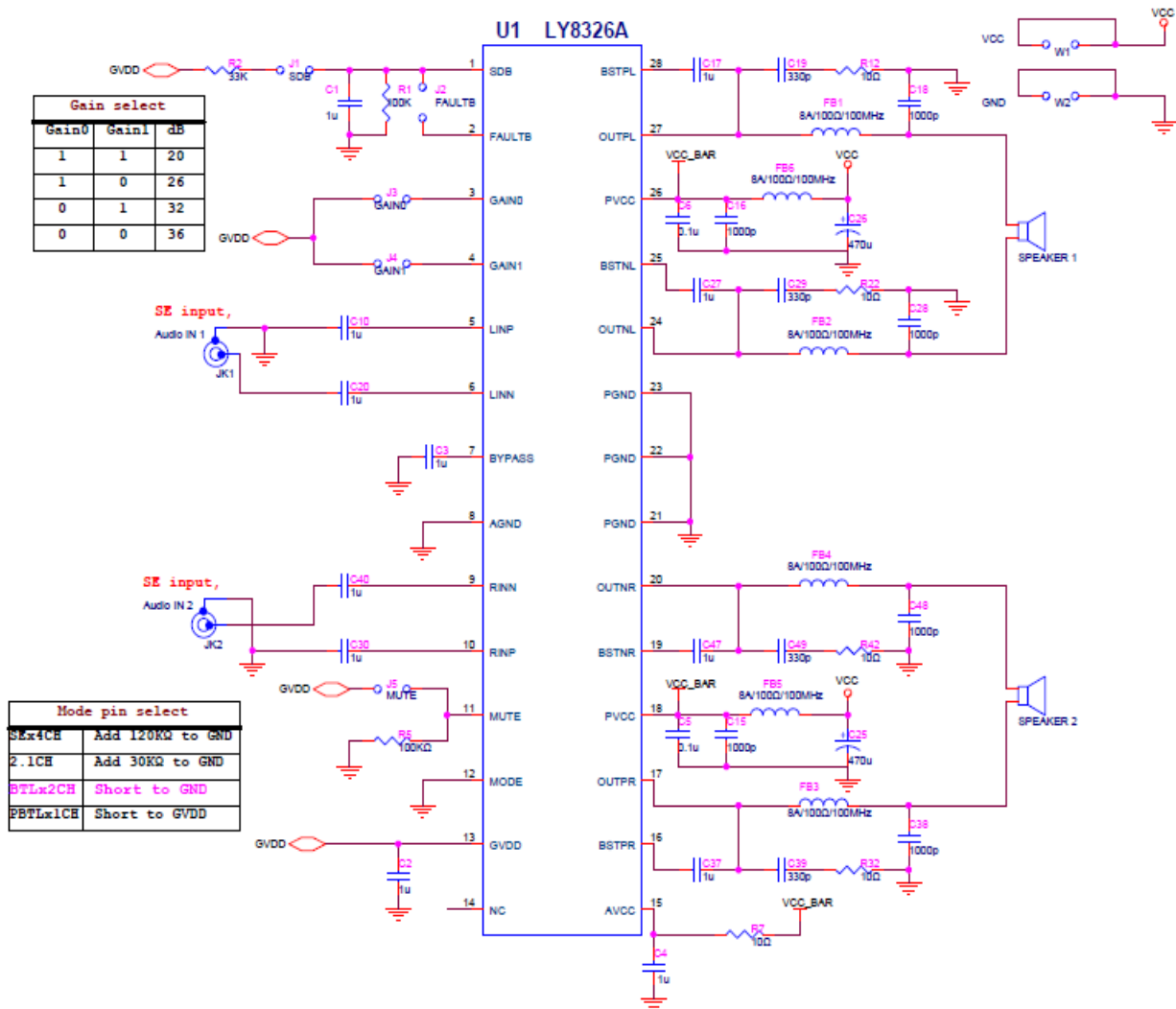


Figure 1. LY8326 Application Circuit with BTLx2 Schematic

(*3) The device must be mounted to the PCB board and increase a large area of copper or recommended to use external heat sink. For best performance, when driving $\leq 12V/4\Omega$ power and loading.

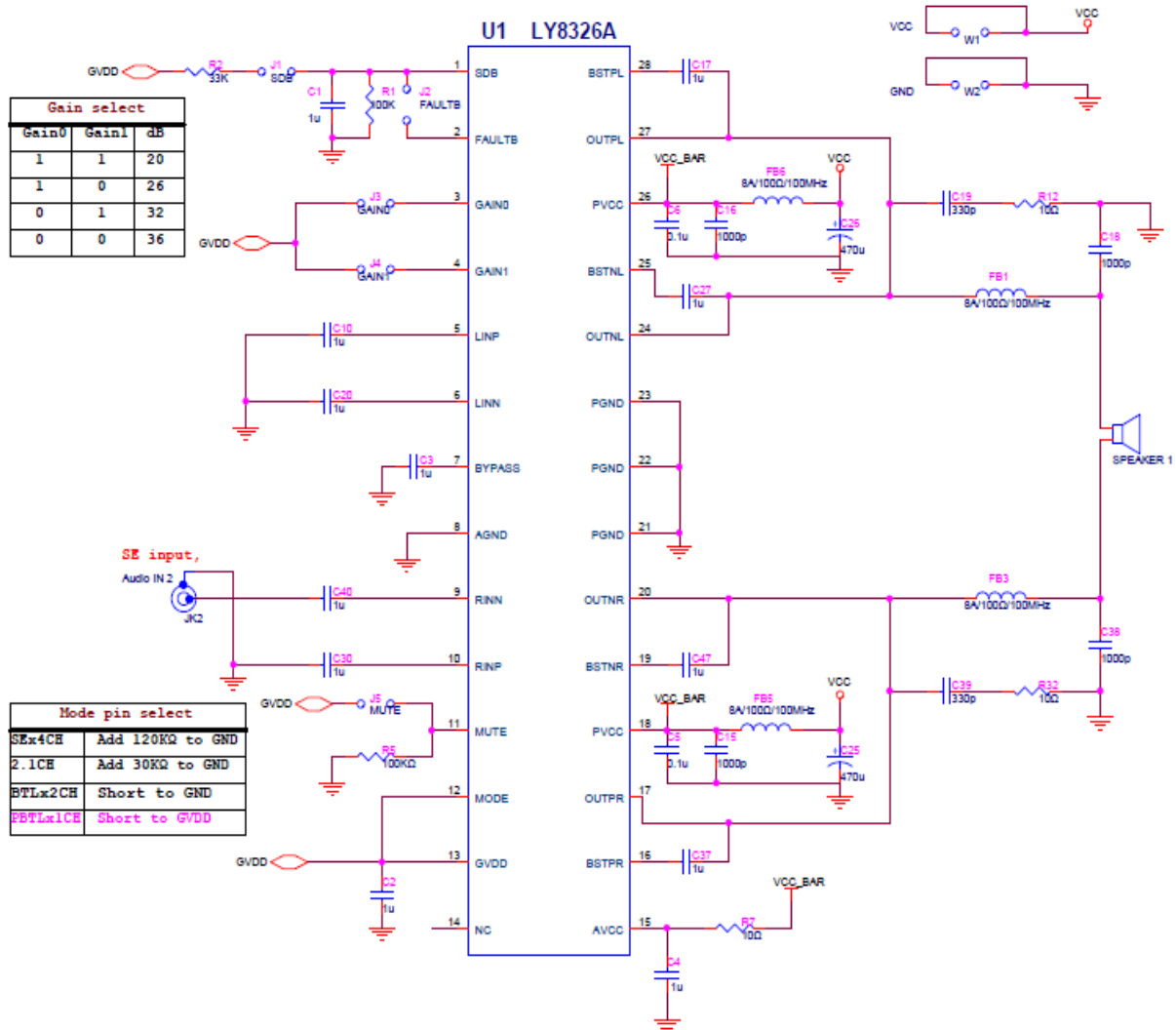


Figure 2. LY8326 Application Circuit with PBTLx1 Schematic

(*3) The device must be mounted to the PCB board and increase a large area of copper or recommended to use external heat sink. For best performance, when driving $<12V/4\Omega$ power and loading.,

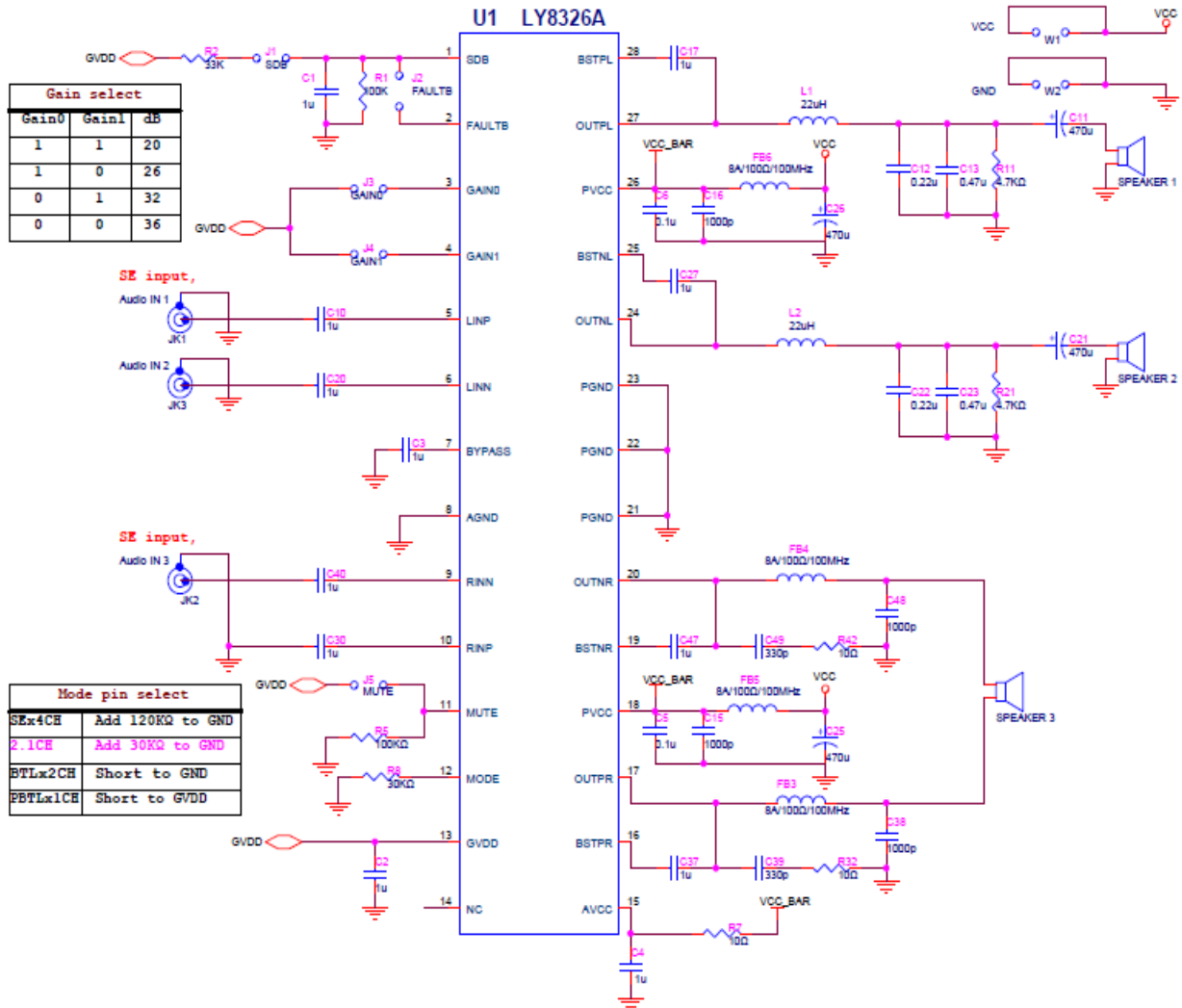


Figure 3. LY8326 Application Circuit with 2.1CH Schematic

(*3) The device must be mounted to the PCB board and increase a large area of copper or recommended to use external heat sink. For best performance, when driving $<12V/4\Omega$ power and loading.

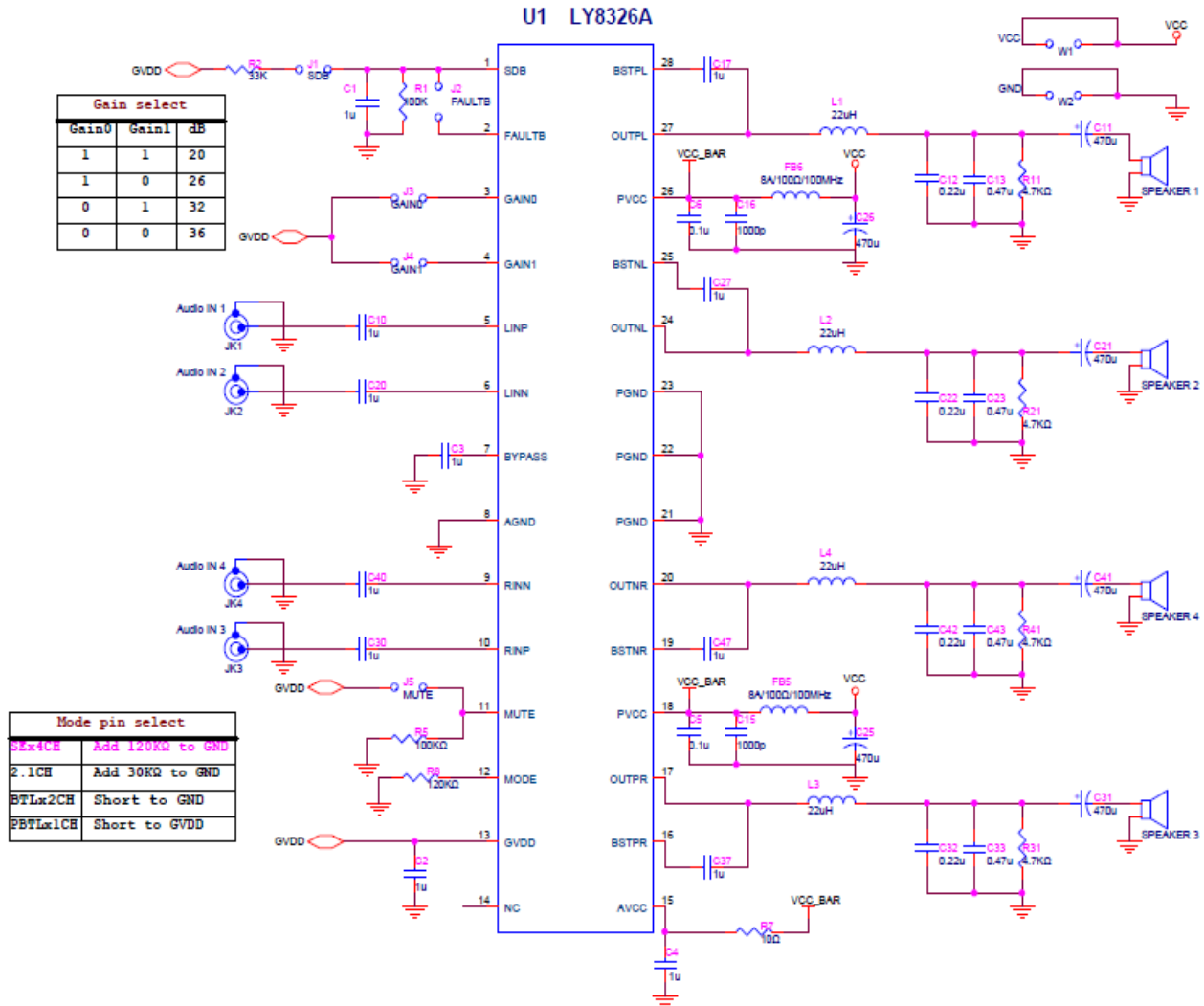


Figure 4. LY8326 Application Circuit with SEx4 mode Schematic

(*3) The device must be mounted to the PCB board and increase a large area of copper or recommended to use external heat sink. For best performance, when driving $12V/4\Omega$ power and loading.

ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	RATING	UNIT
Supply Voltage	PVCC	30	V
Operating Temperature	T _A	-40 to 85 (I grade)	°C
Input Voltage	V _I	-0.3V to PVCC +0.3V	V
Storage Temperature	T _{STG}	-65 to 150	°C
Power Dissipation	P _D	Internally Limited	W
ESD Susceptibility	V _{ESD}	2000	V
Junction Temperature	T _{JMAX}	150	°C
Soldering Temperature (under 10 sec)	T _{SOLDER}	260	°C



ELECTRICAL CHARACTERISTICS (1) (TA = 25°C)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP. ^{*2}	MAX.	UNIT	
Power supply voltage	PVCC	PVCC, AVCC	6.3	-	24	V	
Oscillator frequency	fosc		-	333	-	KHz	
High-level input voltage	VIH	SDB, MUTE, GAIN0, GAIN1	2	-	-	V	
Low-level input voltage	VIL	SDB, MUTE, GAIN0, GAIN1	-	-	0.3	V	
Quiescent Current	Iq	SD ≥ 2.0V, MUTE=0V, no Load, BTL Mode.	PVCC=7.4V	-	17	-	mA
			PVCC=8.4V	-	18	-	
			PVCC=12V	-	20	-	
			PVCC=19V	-	27	-	
			PVCC=24V	-	33	-	
Quiescent Current (in Mute Mode)		SD ≥ 2.0V, MUTE ≥ 2.0V, no Load, BTL Mode.	PVCC=7.4V	-	17	-	mA
			PVCC=8.4V	-	18	-	
			PVCC=12V	-	20	-	
			PVCC=19V	-	27	-	
			PVCC=24V	-	33	-	
Shutdown Current	ISD	VSHUTDOWN ≤ 0.8V, No Load	PVCC=7.4V	-	26	-	uA
			PVCC=8.4V	-	28	-	
			PVCC=12V	-	88	-	
			PVCC=19V	-	53	-	
			PVCC=24V	-	74	-	
Gain	G	Gain0=0	Gain1=0	-	36	-	dB
			Gain1=1	-	32	-	
		Gain0=1	Gain1=0	-	26	-	
			Gain1=1	-	20	-	
Gate Drive supply	GVDD		-	6.78	-	V	
Bypass output voltage	VBYPASS	PVCC=7~24V,	-	2.95	-	V	
Output offset voltage	VOS	VI=0V, Mute mode, BTL Mode	-	7.0	-	mV	
Thermal shutdown temperature	TSD	Shutdown temp.	-	160	-	°C	
		Restore temp.	-	110	-		
Start-up time from shutdown	Zi	PVCC=6.3V~24V, Ci=1uF, BTL mode.	Cbypass=0.1μF	-	48	-	ms
			Cbypass=1μF	-	440	-	
			Cbypass=2.2μF	-	760	-	
			Cbypass=4.7μF	-	1440	-	

(*2) Typical values are included for reference only and are not guaranteed or tested.
 Typical values are measured at PVCC = PVCC(TYP.) and TA = 25°C



OPERATING CHARACTERISTICS (2) (T_A = 25°C)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP. ^{*2}	MAX.	UNIT	
Supply ripple rejection	Ksvr	Gain=20, R _L =4Ω, BTL mode Vripple = 200mVpp at 1kHz, Input=GND, f=217Hz	P _{VCC} =8.4V	-	74.6	-	dB
			P _{VCC} =12V	-	74.5	-	
			P _{VCC} =19V	-	81	-	
Output voltage noise	V _n	input=AC GND, Gain=20dB, A-weighting, f=20Hz to 20kHz, R _L =4Ω,	P _{VCC} =8.4V	-	140	-	uV
			P _{VCC} =12V	-	155	-	
			P _{VCC} =19V	-	182	-	
Signal-to-noise ratio	SNR	BTL Mode , input=GND, Gain=20dB, R _L =4Ω, f=1kHz, Output=1W	P _{VCC} =8.4V	-	85	-	dB
			P _{VCC} =12V	-	84	-	
			P _{VCC} =19V	-	83	-	
Crosstalk	C _s	BTL Mode , input=SE mode, Gain=20dB, R _L =4Ω, f=1KHz, P _o =1W, L to R,	P _{VCC} =8.4V	-	92.8	-	dB
			P _{VCC} =12V	-	95.7	-	
			P _{VCC} =19V	-	93.3	-	
		BTL Mode , input=SE mode, Gain=20dB, R _L =4Ω, f=1KHz, P _o =1W, R to L,	P _{VCC} =8.4V	-	90.5	-	
			P _{VCC} =12V	-	89.9	-	
P _{VCC} =19V	-	88.9	-				

(*2) Typical values are included for reference only and are not guaranteed or tested.
 Typical values are measured at P_{VCC} = P_{VCC}(TYP.) and T_A = 25°C

OPERATING CHARACTERISTICS (3) (T_A = 25°C)

BTL Mode (Stereo) Output Power

PARAMETER	SYMBOL	Voltage	R _L =4Ω ^{*2}				R _L =8Ω ^{*2}			
			1 Channel		2 Channel		1 Channel		2 Channel	
			10%	1%	10%	1%	10%	1%	10%	1%
		7V	5.6	4.7	5.7	4.7	3.3	2.7	3.2	2.6
		7.4V	6.4	5.3	6.4	5.3	3.7	3	3.5	2.9
		8V	7.5	6.2	7.5	6.2	4.3	3.5	4.1	3.4
		8.4V	8.2	7	8.2	6.7	4.7	4	4.6	3.9
		9V	9.5	7.9	9.4	7.8	5.5	4.7	5.2	4.5
		10V	11.5	10	11.6	9.4	6.7	5.6	6.5	5.4
		12V	17	14	16.7	13.8	9.7	7.9	9.4	7.7
		14V	23	19	22.5 ^{*3}	18.3 ^{*3}	13	11	12.5	10.5
		16V	29	24	29 ^{*3}	24.5 ^{*3}	17	14.5	17	14
		18V	37 ^{*3}	31 ^{*3}	36 ^{*3}	29.5 ^{*3}	22	18	21	17
		19V	40.5 ^{*3}	34 ^{*3}	40 ^{*3}	33.5 ^{*3}	24.5	20	23.5	19.5
		20V	-	-	-	-	27	22	26	21.5
		22V	-	-	-	-	32.5	27	32 ^{*3}	26.5 ^{*3}
		24V	-	-	-	-	38 ^{*3}	32 ^{*3}	37.5 ^{*3}	31 ^{*3}

(*3) The device must be mounted to the PCB board and increase a large area of copper or recommended to use external heat sink.

For best performance, when driving <12V/4Ω power and loading.



PBTL Mode (Mono) Output Power

PARAMETER	SYMBOL	Voltage	RL=2Ω ^{*2}		RL=3Ω ^{*2}		RL=4Ω ^{*2}		RL=8Ω ^{*2}	
			10%	1%	10%	1%	10%	1%	10%	1%
			7V	11	9.2	8.2	6.9	6.4	5.3	3.4
7.4V	12.5	10.5	9	7.5	7.2	6.1	3.9	3.2		
8V	14.5	12.2	10.5	8.7	8.4	7.1	4.5	3.7		
8.4V	16	13	11.5	9.8	9.3	7.9	5	4.2		
9V	18	15	13	11	10.5	9.1	5.7	4.8		
10V	22	19	16.5	13.5	13	11	7.1	6		
12V	31	26	24	20	19	16	10	8.5		
14V	40 ^{*3}	35 ^{*3}	32	27	26	22	13.5	11.9		
16V	-	-	42 ^{*3}	35 ^{*3}	33	29	18	15.5		
18V	-	-	-	-	42 ^{*3}	34.5 ^{*3}	23	19		
19V	-	-	-	-	47 ^{*3}	39 ^{*3}	26	21.5		
20V	-	-	-	-	-	-	28	23		
22V	-	-	-	-	-	-	35	29		
24V	-	-	-	-	-	-	41 ^{*3}	34 ^{*3}		

(*2) Typical values are included for reference only and are not guaranteed or tested.

Typical values are measured at PVCC = PVCC(TYP.) and TA = 25°C.

The test machine : Audio Precision SYS-2712A and AUX-0025.

(*3) The device must be mounted to the PCB board and increase a large area of copper or recommended to use external heat sink.

For best performance, when driving ≤ 12V/4Ω power and loading,

SE Mode (Single-End) Output Power

PARAMETER	SYMBOL	Voltage	RL=4Ω ^{*2}				RL=8Ω ^{*2}			
			1 Channel		4 Channel		1 Channel		4 Channel	
			10%	1%	10%	1%	10%	1%	10%	1%
7V		1.55	1	1.5	1.15	0.9	0.5	0.8	0.55	
7.4V		1.8	1.15	1.7	1.3	1	0.6	0.9	0.6	
8V		2.1	1.35	2	1.6	1.1	0.7	1.1	0.9	
8.4V		2.3	1.45	2.1	1.7	1.3	0.8	1.2	1	
9V		2.6	1.65	2.5	2	1.5	0.9	1.4	1.2	
10V		3.2	2.1	3	2.5	1.8	1.1	1.7	1.4	
12V		4.7	3	4.5	3.5	2.5	1.65	2.5	2	
14V		6.4	4.3	6	5	3.5	2.5	3.4	2.8	
16V		8.4	5.8	8.5	6.5	4.6	3.5	4.5	3.5	
18V		10.5	7.9	10 ^{*3}	8.5 ^{*3}	5.9	4.5	5.7	4.5	
19V		12.3	9.4	11.5 ^{*3}	9 ^{*3}	6.5	5.3	6.4	5	
20V		13	10.5	12.5 ^{*3}	10 ^{*3}	7.2	5.7	7	5.5	
22V		16	12	15 ^{*3}	12 ^{*3}	8.8	6.5	8.5	6.5	
24V		19	14.5	18 ^{*3}	14 ^{*3}	10.5	7.8	10 ^{*3}	8 ^{*3}	

(*2) Typical values are included for reference only and are not guaranteed or tested.

Typical values are measured at PVCC = PVCC(TYP.) and TA = 25°C.

The test machine : Audio Precision SYS-2712A and AUX-0025.

(*3) The device must be mounted to the PCB board and increase a large area of copper or recommended to use external heat sink.

For best performance, when driving < 12V/4Ω power and loading.



TYPICAL PERFORMANCE CHARACTERISTICS

Figure 5

THD+N vs. Output Power (@ **Output type=BTL Mode, RL=4Ω, f=1kHz, Gain=20dB**)

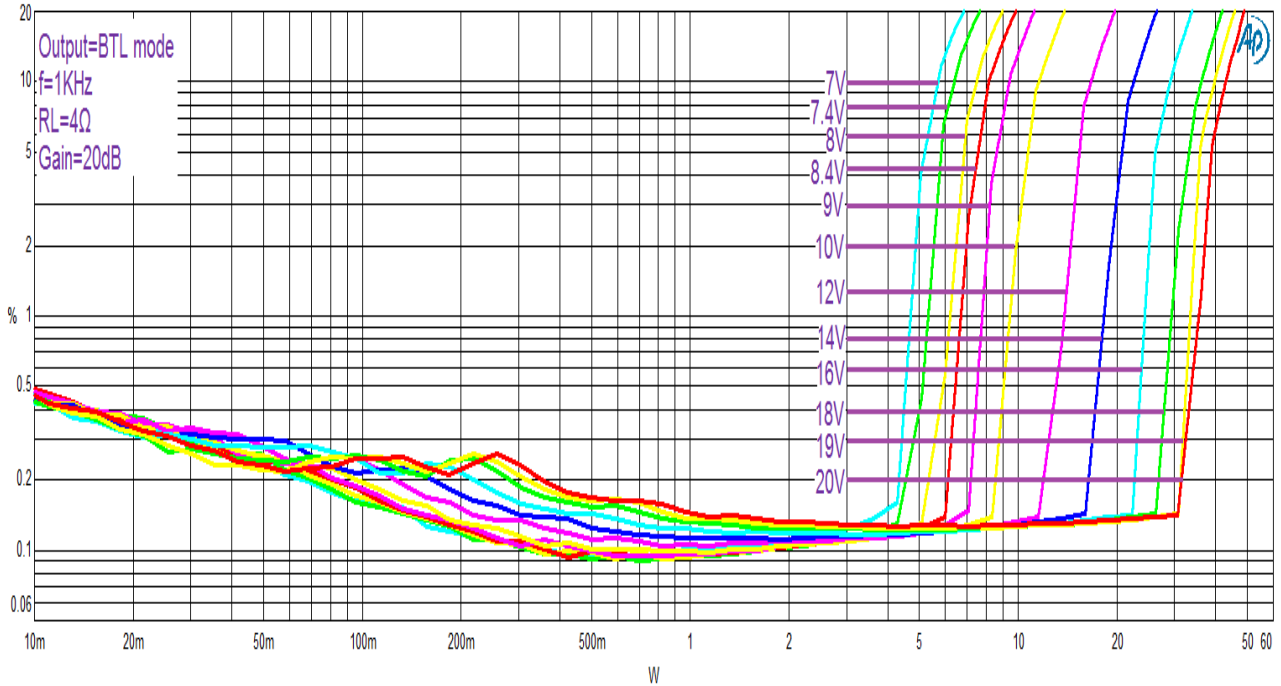


Figure 6

THD+N vs. Output Power (@ **Output type=BTL Mode, RL=8Ω, f=1kHz, Gain=20**)

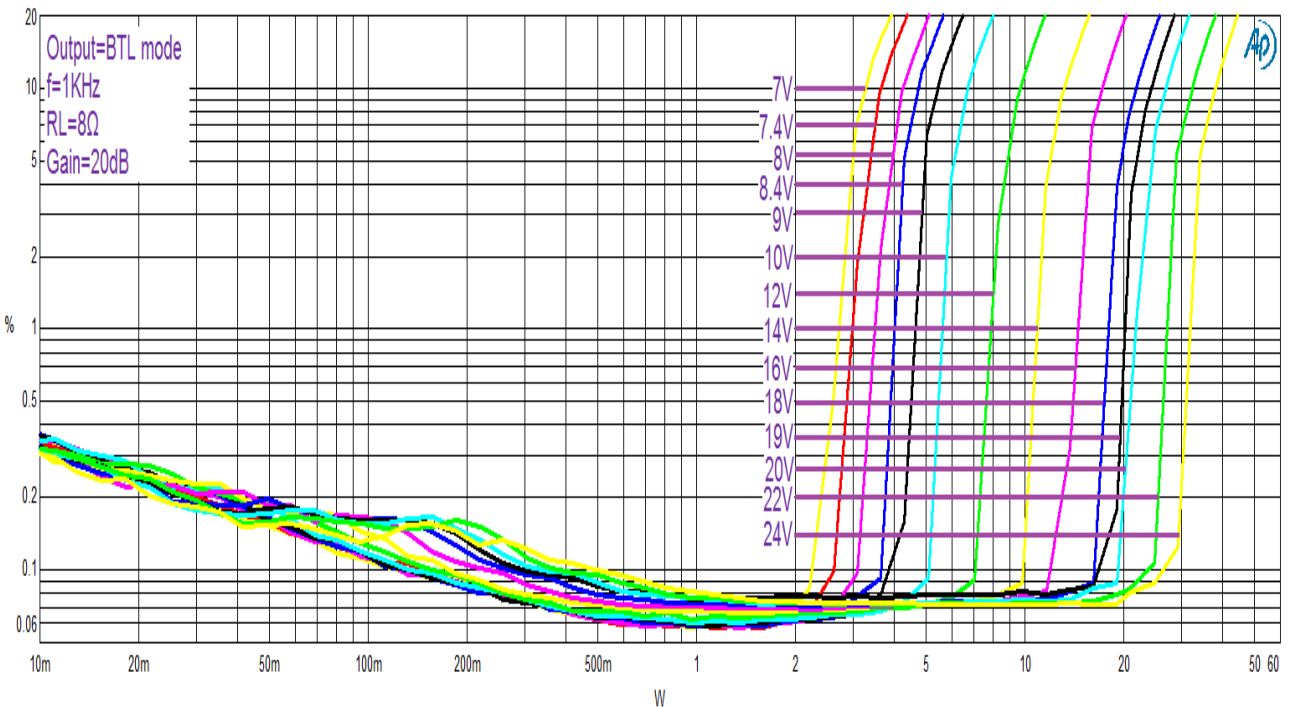




Figure 7
THD+N vs. Output Power (@ **Output type=PBTL Mode, $R_L=2\Omega$, $f=1\text{kHz}$, Gain=20**)

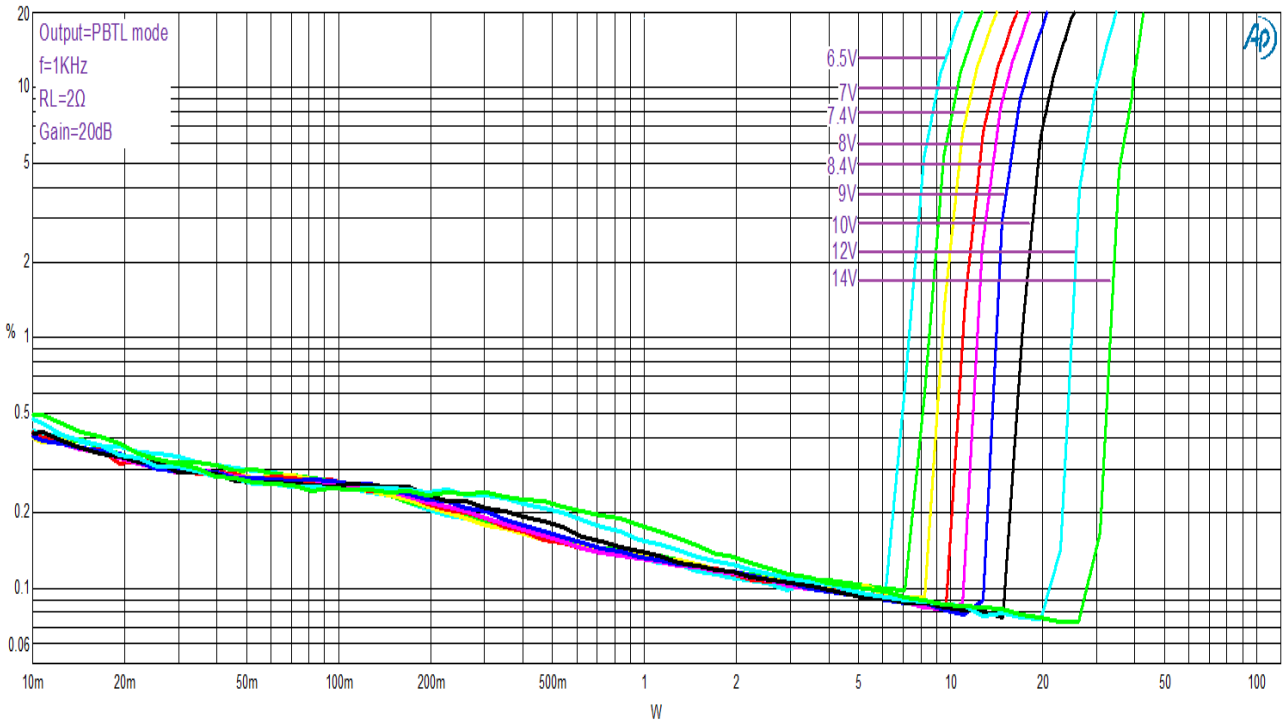


Figure 8
THD+N vs. Output Power (@ **Output type=PBTL Mode, $R_L=3\Omega$, $f=1\text{kHz}$, Gain=20**)

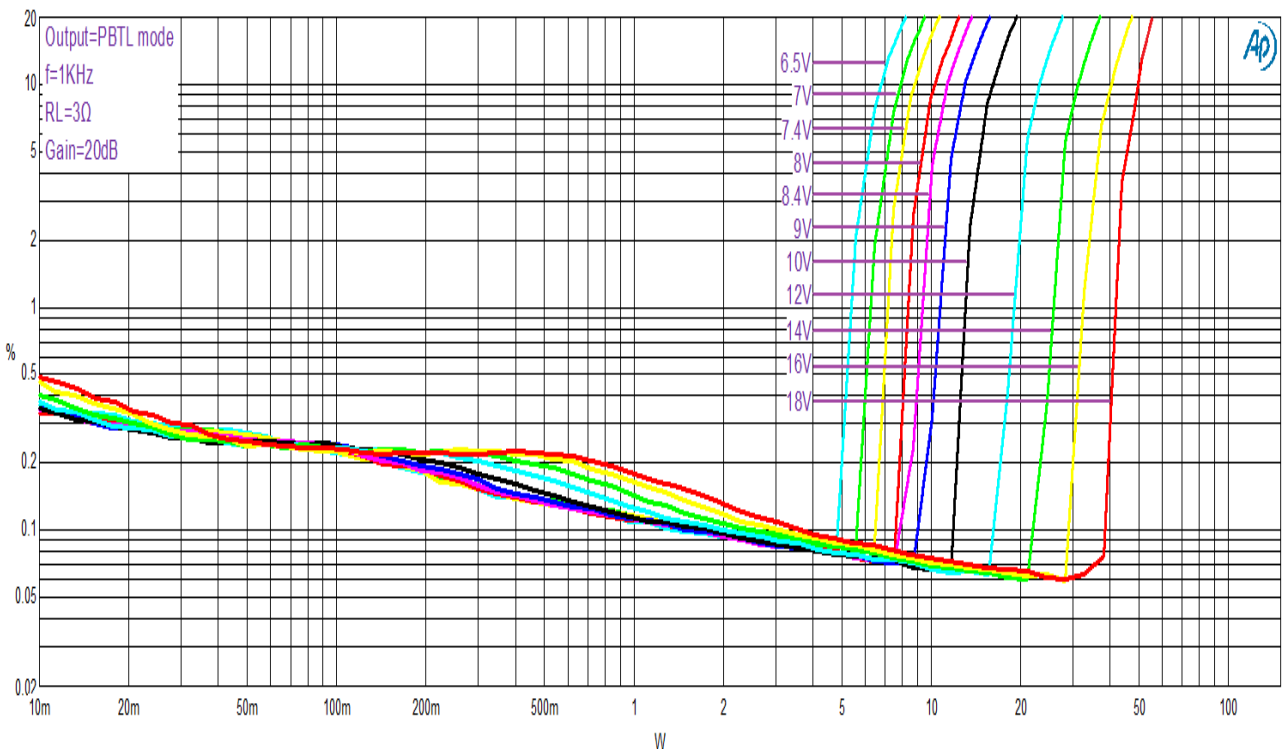




Figure 9
THD+N vs. Output Power (@ **Output type=PBTL Mode**, $R_L=4\Omega$, $f=1\text{kHz}$, Gain=20)

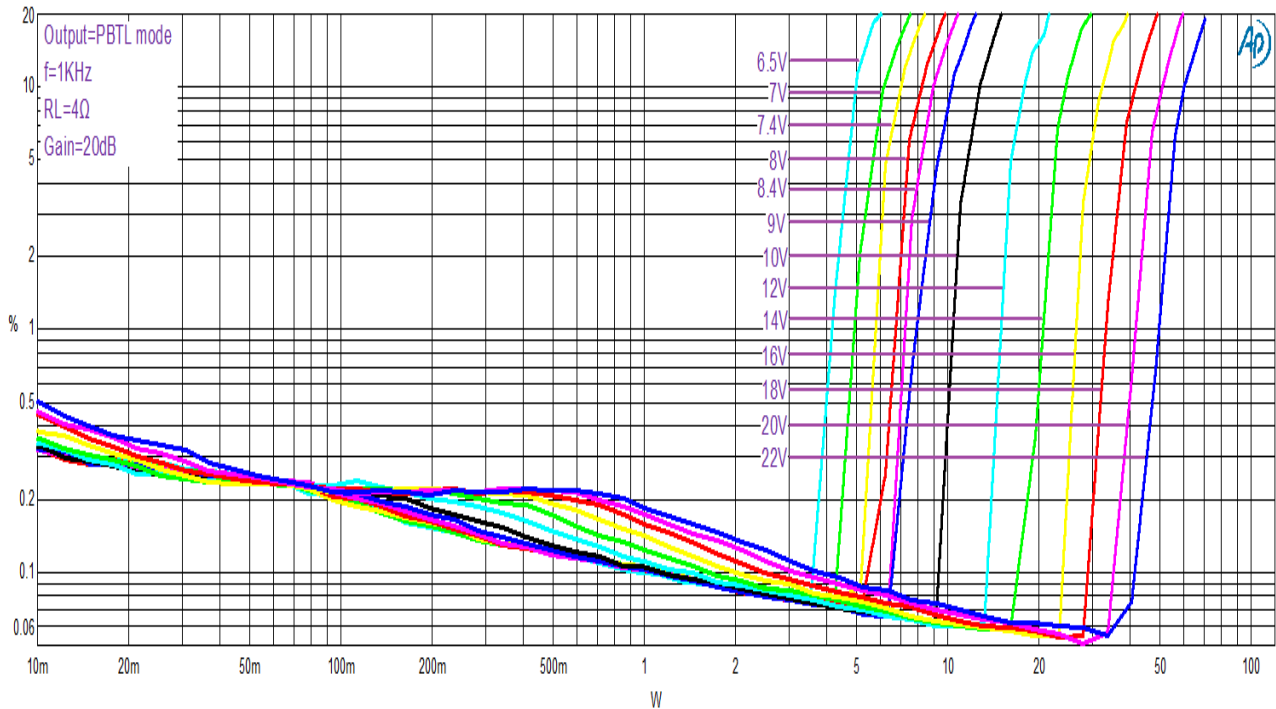


Figure 10
THD+N vs. Output Power (@ **Output type=SE Mode**, $R_L=4\Omega$, $f=1\text{kHz}$, Gain=20)

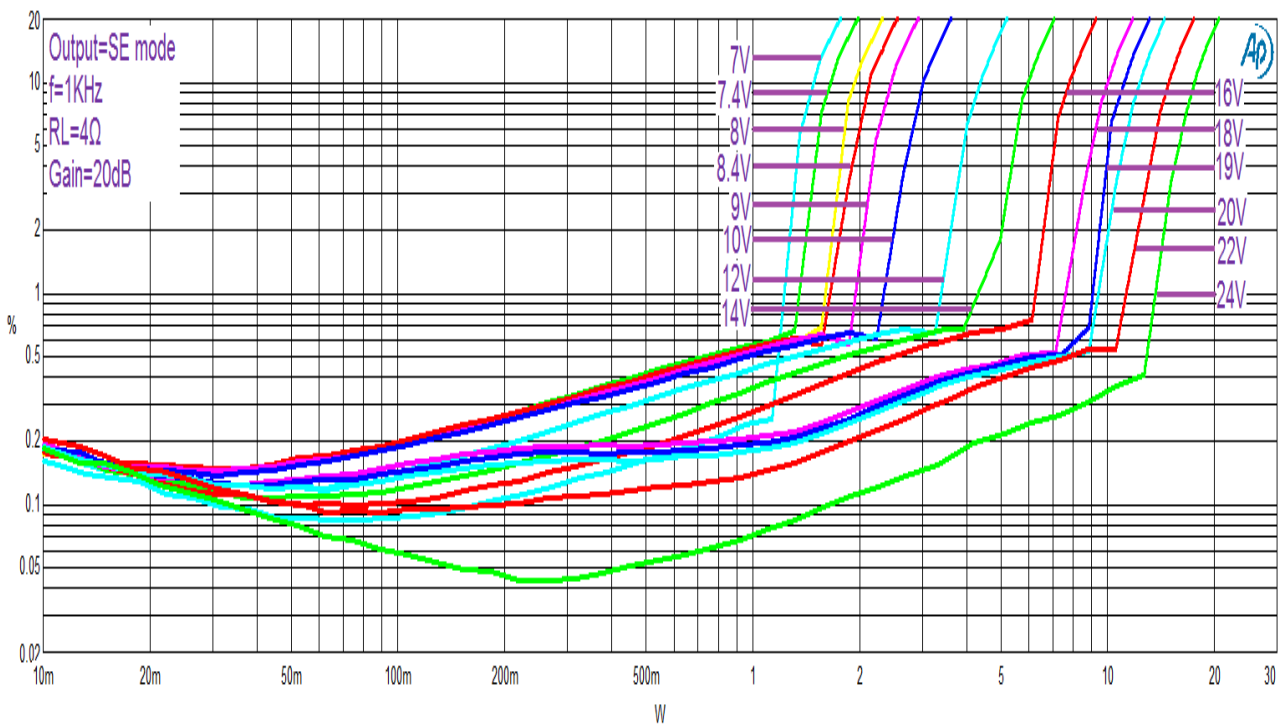




Figure 11
THD+N vs. Output Power (@ **Output type=SE Mode, RL=8Ω, f=1kHz, Gain=20**)

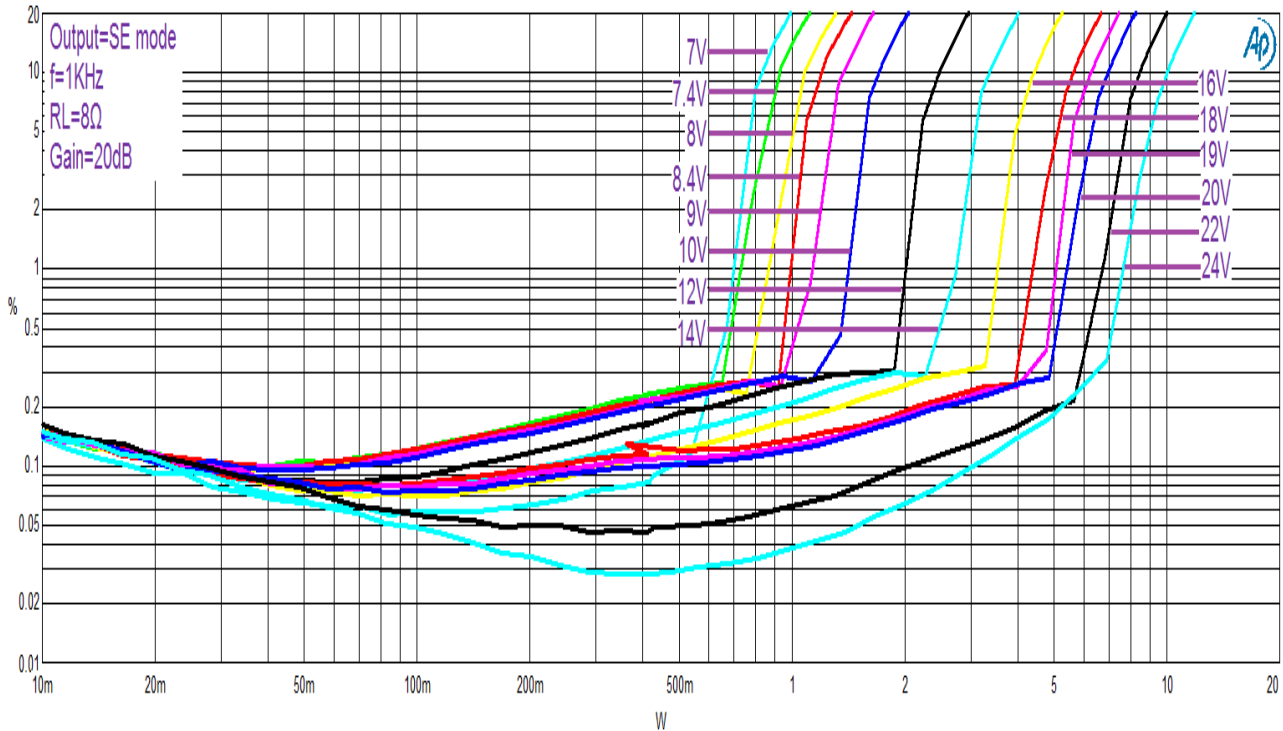


Figure 12
Supply ripple rejection (Ksvr, **RL=4Ω, BTL mode**)

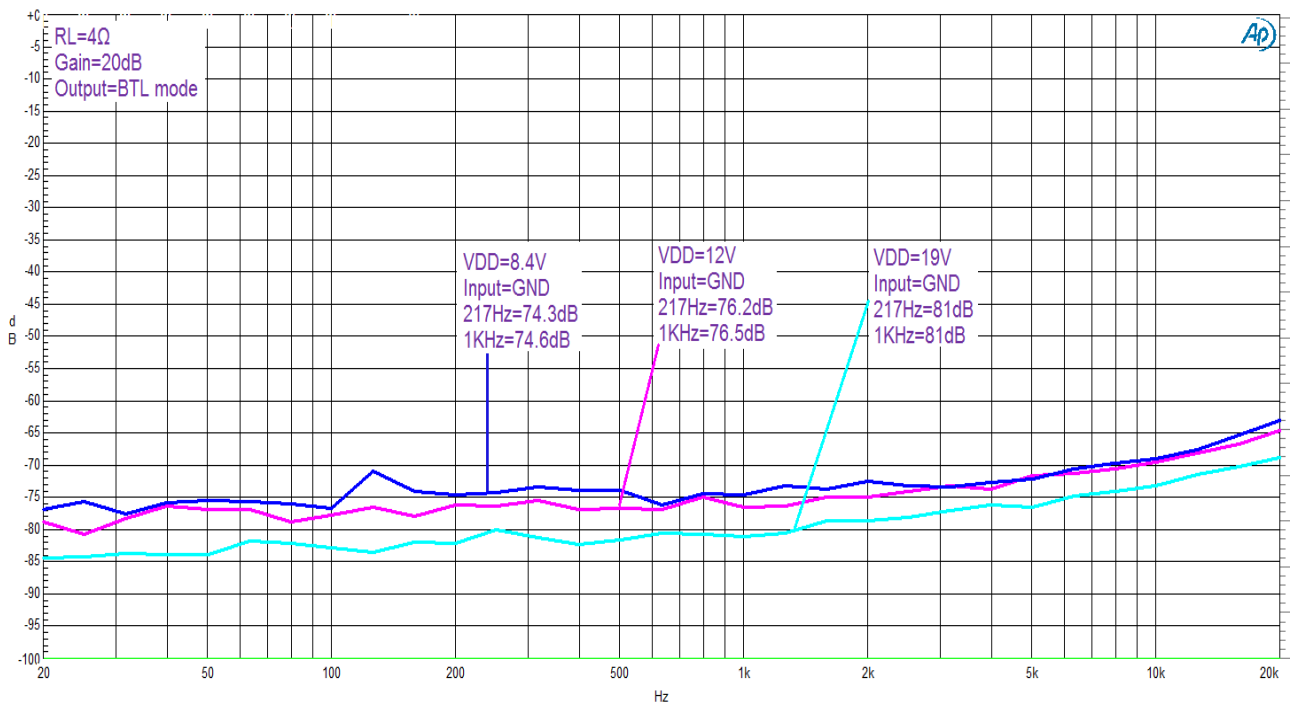




Figure 13
SNR vs. Noise Level (BTL mode)

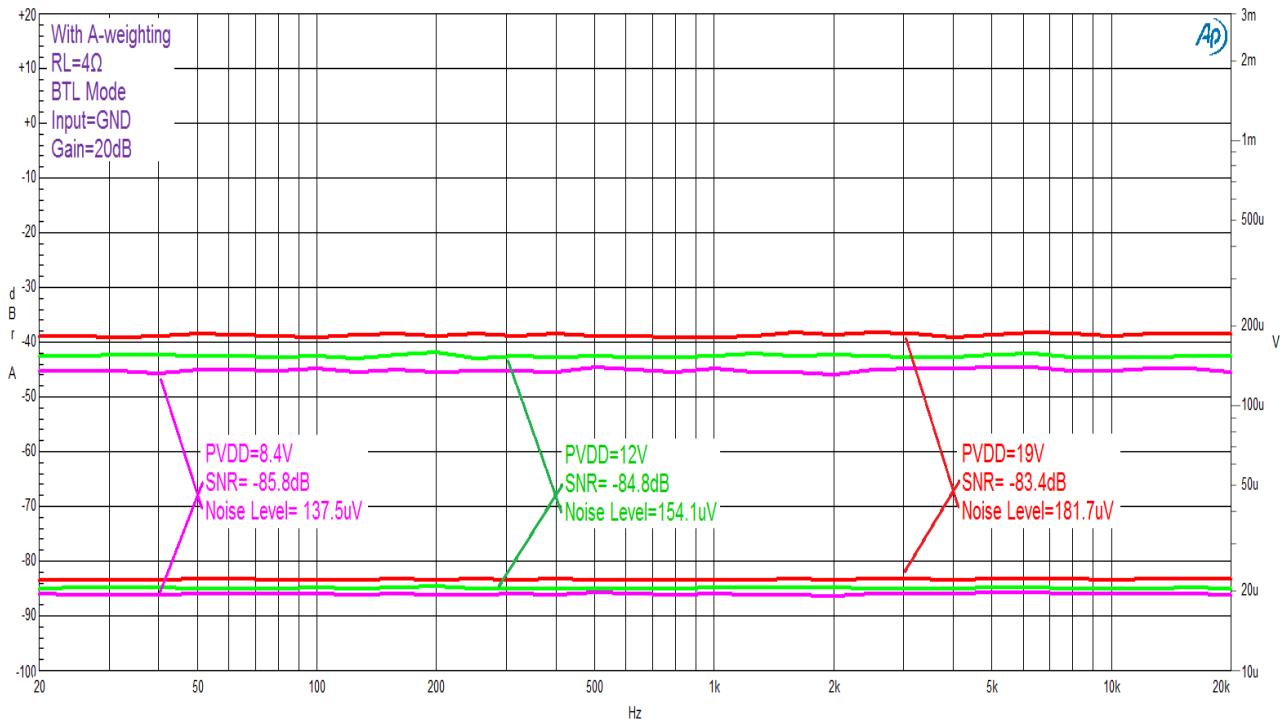


Figure 14
Crosstalk vs. Frequency (BTL mode, L to R)

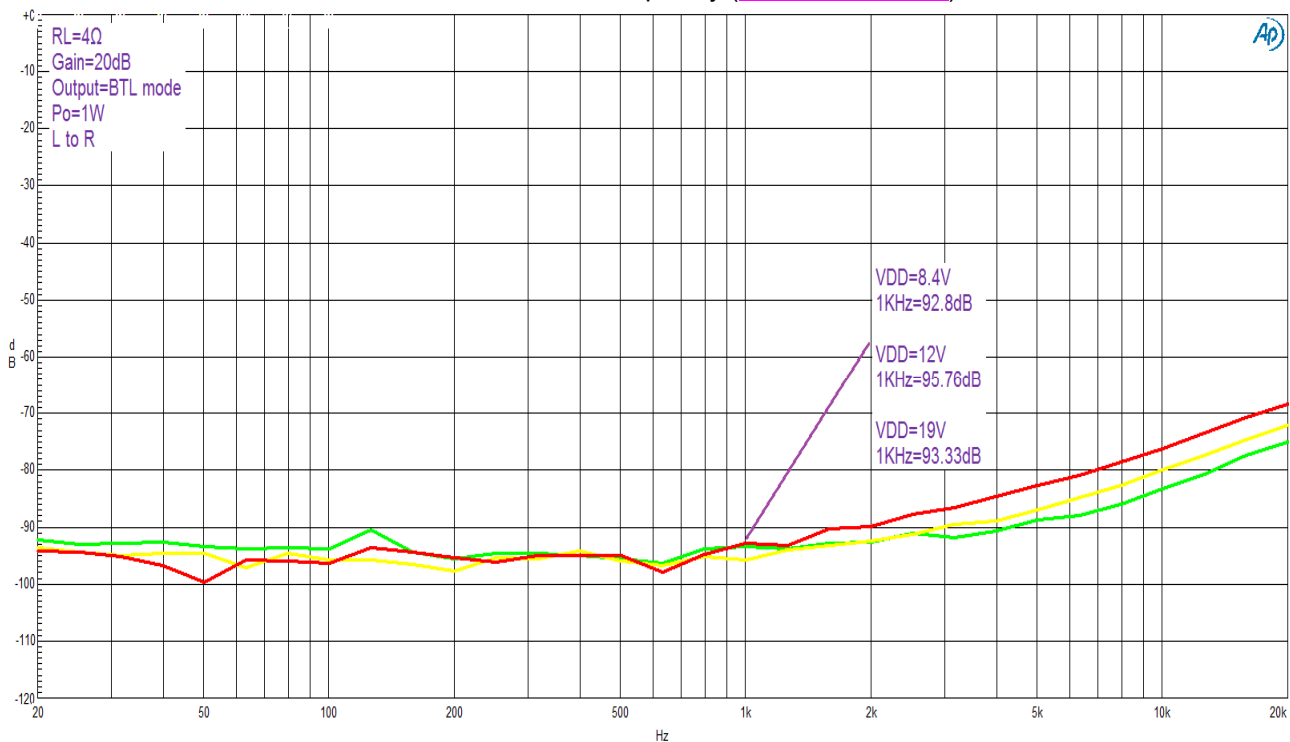




Figure 15
Crosstalk vs. Frequency (BTL mode, R to L)

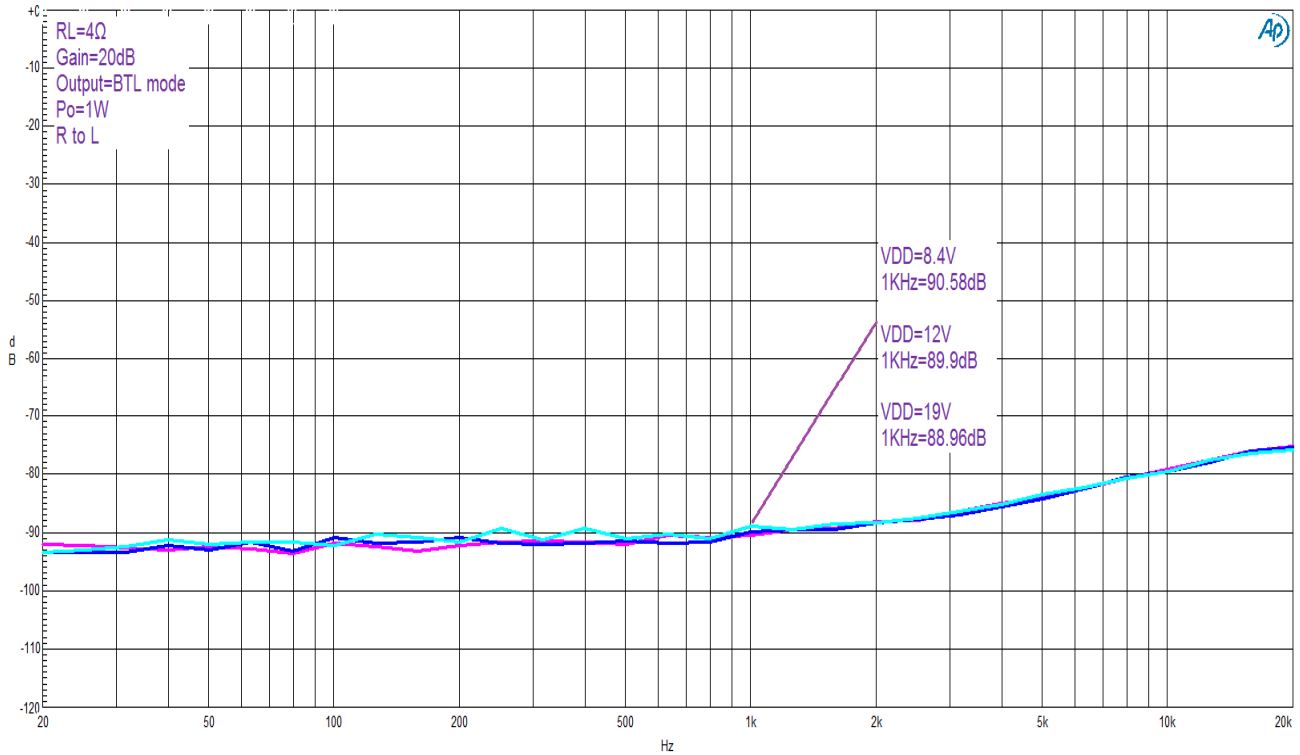
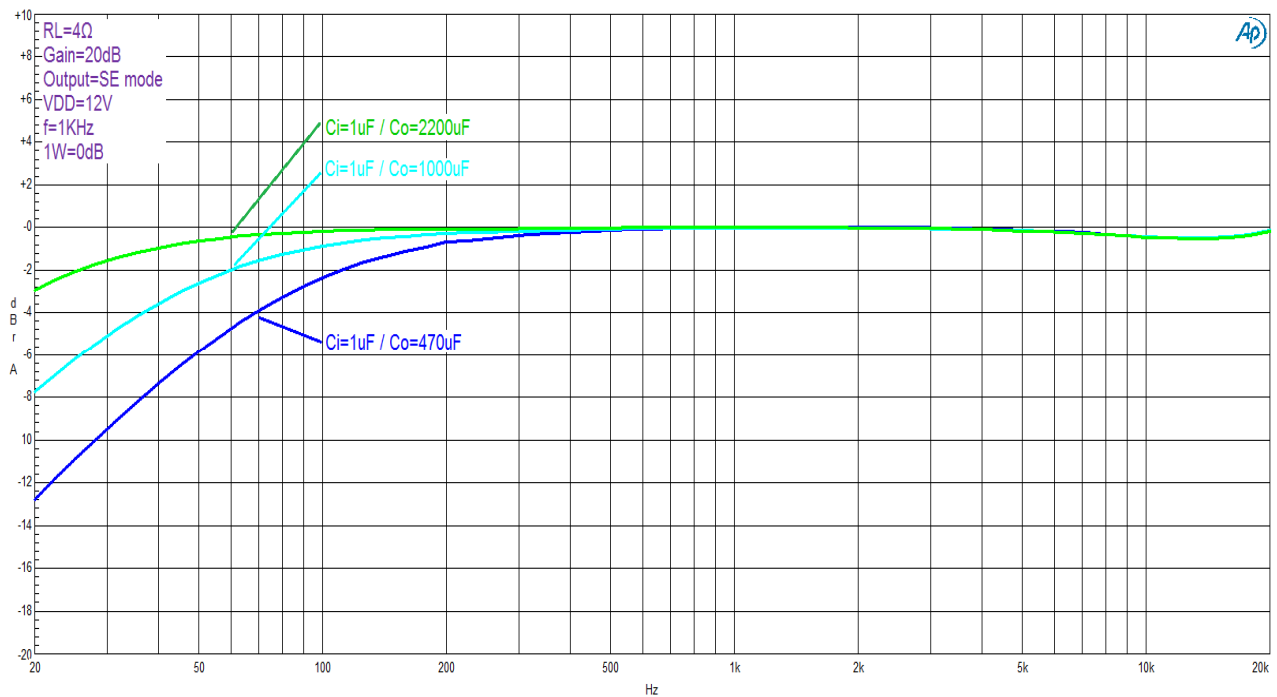
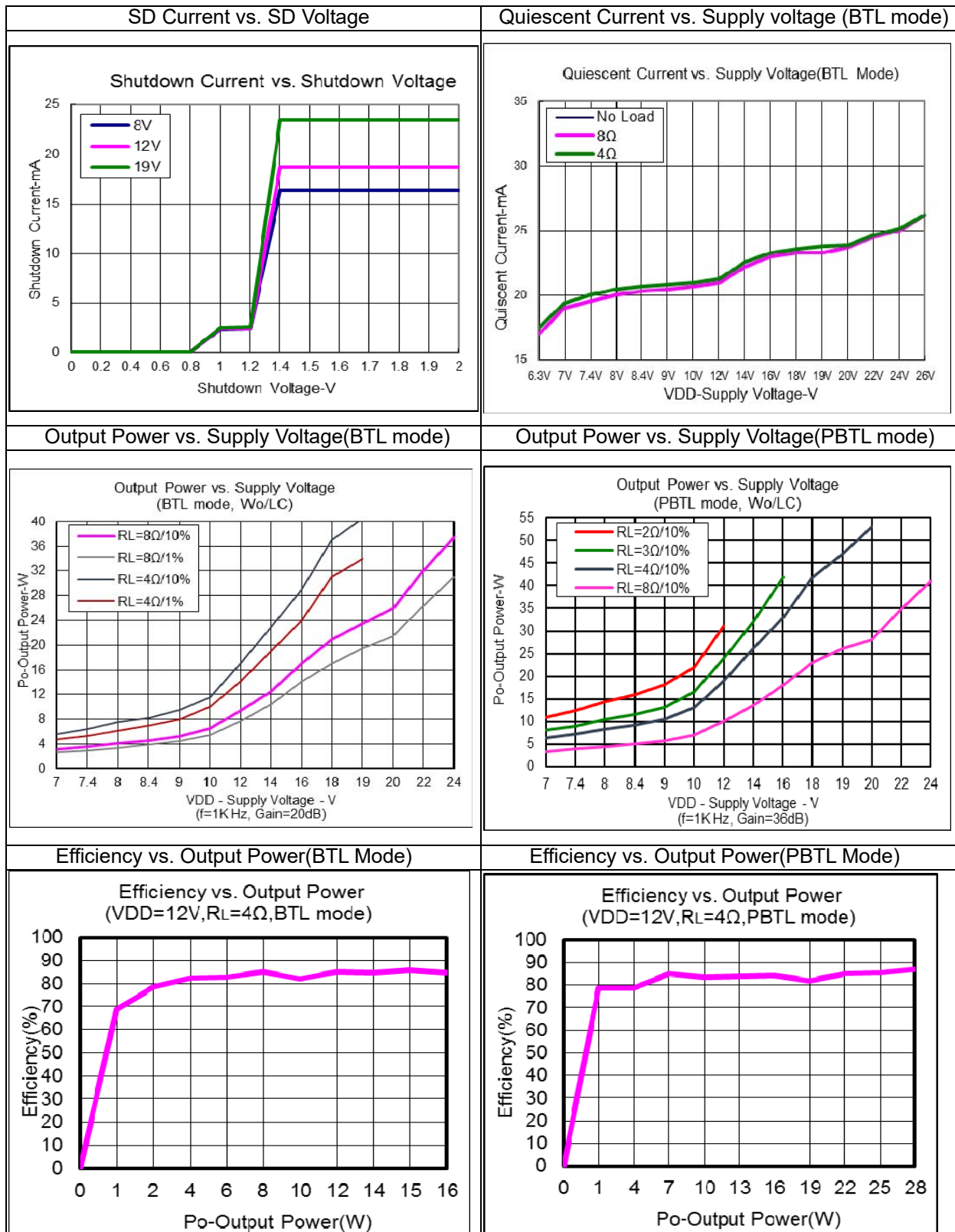


Figure 16
Frequency vs. Response (SE mode)







APPLICATION INFORMATION

Input Capacitors (Ci)

In typical application, Ci and the input resistance of the amplifier (Ri) form a high-pass filter with the corner frequency (fc) determined in equation.

$$f_c = 1 / (2\pi R_i C_i)$$

The value of the input capacitor is important to consider as it directly affects the bass (low frequency) performance of the circuit.

For example

If the gain is known and is constant, use Ri from Table 1 to calculate Ci and use below equation.

$$C_i = 1 / (2\pi R_i f_c)$$

A.) If Ri is 36dB(8.2 kΩ) and the specification calls for a flat bass response down to 20 Hz.

$C_i = 1 / (2\pi \times 8.2K\Omega \times 20Hz) = 0.9705\mu F$, One would likely choose a value of 1.0uF as this value is commonly used.

B.) If Ri is 32dB(12.5 kΩ) and the specification calls for a flat bass response down to 20 Hz.

$C_i = 1 / (2\pi \times 12.5K\Omega \times 20Hz) = 0.6366\mu F$, One would likely choose a value of 0.68uF as this value is commonly used.

C.) If Ri is 26dB(25 kΩ) and the specification calls for a flat bass response down to 20 Hz.

$C_i = 1 / (2\pi \times 25K\Omega \times 20Hz) = 0.3183\mu F$, One would likely choose a value of 0.33uF as this value is commonly used.

D.) If Ri is 20dB(50 kΩ) and the specification calls for a flat bass response down to 20 Hz.

$C_i = 1 / (2\pi \times 50K\Omega \times 20Hz) = 0.1592\mu F$, One would likely choose a value of 0.15uF as this value is commonly used.

Input Resistors (Ri) and Gain

The LY8326A support four type digital gain selectable. So changing the gain setting can vary the input resistance of the amplifier from 8.2 kΩ ±20% to 50 kΩ ±20%. As a result, cutoff frequency may change when changing gain steps. (Reference table 1)

Gain setting (GAIN0 and GAIN1)

The gain of the LY8326A is set by two input pins, GAIN0 and GAIN1.

Table 1. Gain Setting

Gain0	Gain1	Amplifier Gain (dB) TYP.	Input Impedance (KΩ)
0	0	36	8.2
0	1	32	12.5
1	0	26	25
1	1	20	50

The gains listed in Table 1 are realized by changing the taps on the input resistors inside the amplifier. The actual gain

settings are controlled by ratios of resistors, so the gain variation from part-to-part is small.

However, the input impedance from part-to-part at the same gain may shift by $\pm 20\%$ due to shifts in the actual resistance of the input impedance.

For design purposes, the input resistance should be designed assuming an input impedance of 6.6 k Ω , which is the absolute minimum input impedance of the LY8326A. At the lower gain settings, the input impedance could increase as high as 60 k Ω .

Mode Select

The LY8326A offers the feature of 4 type mode select. Through the pin 12 connection as the following for mode selection.

Table 2. Output Mode Select Table

Mode pin (pin 12)	Mode
0 Ω to GND	BTLx2
30K Ω to GND	2.1 CH
120K Ω to GND	SEx4
0 Ω to GVDD	PBTLx1

Differential Inputs

The differential input stage of the amplifier cancels any noise that appears on both input lines of the channel.

To use the LY8326A with a differential source, connect the positive lead of the audio source to the INP input and the negative lead from the audio source to the INN input. To use the LY8326A with a single-ended source, ac ground the INP or INN input through a capacitor equal in value to the input capacitor on INN or INP and apply the audio source to either input. In a single-ended input application, the unused input should be ac grounded at the audio source instead of at the device input for best noise performance.

For good transient performance, the impedance seen at each of the two differential inputs should be the same. The impedance seen at the inputs should be limited to an RC time constant of 1 ms or less if possible. This is to allow the input dc blocking capacitors to become completely charged during the more power-up time (ms).

If the input capacitors are not allowed to completely charge, there will be some additional sensitivity to component matching which can result in pop if the input components are not well matched.

GVDD Supply

The GVDD Supply is used to power the gates of the output full bridge transistors. It can also be used to supply the control pin voltage divider circuit. Add a 1 μ F capacitor to ground at this pin.

Bypass Capacitor (Cbypass)

The Bypass Capacitor (C3) is the most critical capacitor and serves important functions. During start-up or recovery from shutdown mode, Cbypass determines the rate at which the amplifier starts up. The Cbypass will reduce noise caused by the power supply coupling into the output drive signal. This noise is from the internal analog reference to the amplifier, which appears as degraded the PSRR and THD+N values. The bypass capacitor (C3) with values of 0.1 μ F to 4.7 μ F is recommended for the best THD and noise performance. Therefore, increasing the bypass capacitor reduces clicking and popping noise from power on/off and entering and leaving shutdown.

Power Supply Decoupling Capacitor (Cs)

The LY8326A is a high-performance class-D audio amplifier that requires adequate power supply decoupling to ensure the efficiency is high and total harmonic distortion (THD) is low. For higher frequency transients, spikes, or digital hash on the line, a good low equivalent-series-resistance (ESR) ceramic capacitor, typically 0.1 μ F~1.0 μ F, placed as close as possible to the device PVCC lead works best. Placing this decoupling capacitor close to the LY8326A is very important for the efficiency of the class-D amplifier, because any resistance or inductance in the trace between the device and the capacitor can cause a loss in efficiency. For filtering lower-frequency noise signals, a 470 μ F or greater capacitor placed near the audio power amplifier would also help, so 470 μ F or larger capacitor should be placed on each PVCC terminal.



BST Capacitors

The half H-bridge output stages use only NMOS transistors. Therefore, they require bootstrap capacitors for the high side of each output to turn on correctly. A 1.0uF ceramic capacitor, rated for at least 25V up, must be connected from each output to its corresponding bootstrap input. Specifically, all 1.0uF capacitor must be connected from OUT to BST pin.

The bootstrap capacitors connected between the BST pins and their corresponding outputs function as a floating power supply for the high-side N-channel power MOSFET gate-drive circuitry. During each high-side switching cycle, the bootstrap capacitors hold the gate-to-source voltage high enough to keep the high-side MOSFETs turned on.

Shutdown Function

When the LY8326A not in use. The device will be to turn off the amplifier to reduce power consumption.

When logic **low** is applied to the shutdown pin, this shutdown feature will turns the amplifier off. By switching the shutdown pin connected to GND, the device supply current draw will be minimized in idle mode. The pin cannot be left floating due to the internal did not pull-up.

Mute Function

The Mute pin is an input pin to control the LY8326A output state. A logic **high** is disable the LY8326A outputs.

A logic **low** on this pin enables the outputs. This terminal may be used as a quick disable/enable of outputs when changing channels on a TV or transitioning between different audio sources.

The Mute pin should never be left floating. For power conservation, the SD pin should be used to reduce the quiescent current to the absolute minimum level.

Over-Heat Protection

The LY8326A has a built-in over-heat protection circuit, it will turn off all power output when the chip temperature over 160°C, (There is a ±20°C tolerance on this trip point from device to device.) the chip will return to normal operation automatically after the temperature cool down to 110°C.

Thermal protection faults are NOT reported on the FAULT pin.

Short Circuit Protection and Automatic Recovery Feature

The LY8326A has short circuit protection circuitry on the outputs that prevents damage to the device during output-pin to-output pin shorts. When the short circuit is detected on the outputs, the part immediately goes into shutdown. This is a latched fault and must be reset by cycling the voltage on the shutdown pin to a logic low and back to the logic high, or by cycling the power off and then back on. This clears the short-circuit flag and allows for normal operation if the short was removed. If the short was not removed, the protection circuitry activates again.

If automatic recovery from the short circuit protection latch is desired, connect the FAULT pin directly to the SD pin. This allows the FAULT pin function to automatically drive the SD pin low which clears the short-circuit protection latch.

Single-Ended Output Capacitor Select, (Co)

In single-ended (SE) applications, the dc blocking capacitor forms a high-pass filter with the speaker impedance. The frequency response rolls off with decreasing frequency at a rate of 20 dB/decade. The cutoff frequency is determined by :

$$f_c = 1 / (2\pi R_L C_o)$$

Table 3. Filter Responses Reference Values

Speaker Load RL (Ω)	SE mode - Co Capacitor select(uF)						
	fc=180Hz	fc=120Hz	fc=100Hz	fc=80Hz	fc=60Hz	fc=40Hz	fc=20Hz
4	220	330	390	470	680	1000	2200
6	-	220	-	330	470	680	1500
8	-	-	200	-	330	470	1000

BTL Output (Use an Output Filter for EMI Suppression)

The LY8326A has been tested with a simple ferrite bead filter for some applications. And it passes FCC Class B specifications under these conditions using 25cm twisted speaker wires.

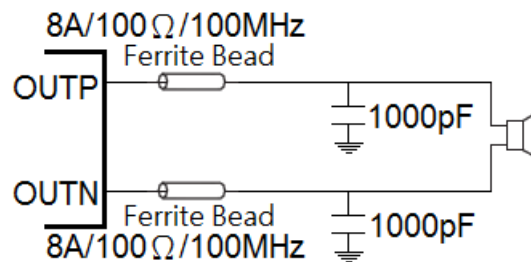


Figure 17. Typical ferrite bead filter example

If there are nearby circuits which are sensitive to noise or there need long speaker wires. It is necessary to add a complete LC reconstruction filter.

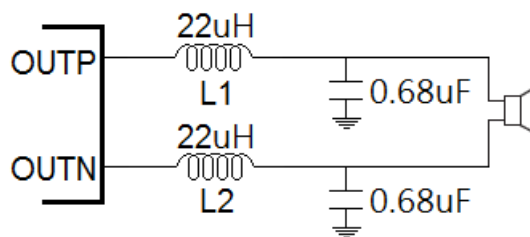


Figure 18. Typical LC output filter, Cutoff Frequency of 40 kHz, Speaker Impedance = 4Ω

The cutoff frequency is determined by :

$$f_c = 1 / (2\pi * \text{SQRT}(LC))$$

Ferrite Bead Filter Considerations

Using the Advanced EMI Suppression Technology in the LY8326A amplifier it is possible to design a high efficiency Class-D audio amplifier while minimizing interference to surrounding circuits. It is also possible with a low-cost ferrite bead filter. In this case it is necessary to carefully select the ferrite bead used in the filter.

One important aspect of the ferrite bead selection is the type of material used in the ferrite bead. Not all ferrite material is alike, so it is important to select a material that is effective in the 10 to 100 MHz range which is key to the operation of the Class D amplifier. And it is important that the ferrite bead is large current enough to maintain its impedance at the peak currents expected for the amplifier. Also, high quality ceramic capacitor is also needed for the ferrite bead filter. A low ESR capacitor with good temperature and voltage characteristics will work best.



PCB Layout

Because the LY8326A is a class-D amplifier that switches at a high frequency, the layout of the PCB should be optimized according to the following guidelines for the best possible performance.

1. Thermal pad—The thermal pad must be soldered to the PCB for proper thermal performance and optimal reliability.
2. Decoupling capacitors—The high-frequency 0.1uF decoupling capacitors should be placed as close to the PVCC pins and AVCC pin terminals as possible.
And the Bypass pin capacitor should also be placed as close to the device as possible.
Large (470uF or greater) bulk power-supply decoupling capacitors should be placed near the device on the PVCC terminals.
3. Grounding—The AVCC pin decoupling capacitor and Bypass pin capacitor should each be grounded to analog ground (AGND).
The PVCC decoupling capacitors should each be grounded to power ground (PGND).
Analog ground and power ground should be connected at the thermal pad, which should be used as a central ground connection or star ground for the LY8326A.
4. Output filter—The reconstruction filter should be placed as close to the output terminals as possible for the best EMI performance. The capacitors should be grounded to power ground.
5. The input resistors need to be very close to the device input pins so noise does not couple on the high impedance nodes between the input resistors and the input amplifier of the device.
6. Making the high current traces going to PVCC, GND, Vo+ and Vo- pins of the device should be as wide as possible to minimize trace resistance.
If these traces are too thin, the device's performance and output power will decrease.
The input traces do not need to be wide, but do need to run side-by-side to enable common-mode noise cancellation.

■ DEMO BOARD INFORMATION

Demo Board Application Circuit (BTLx2 mode)

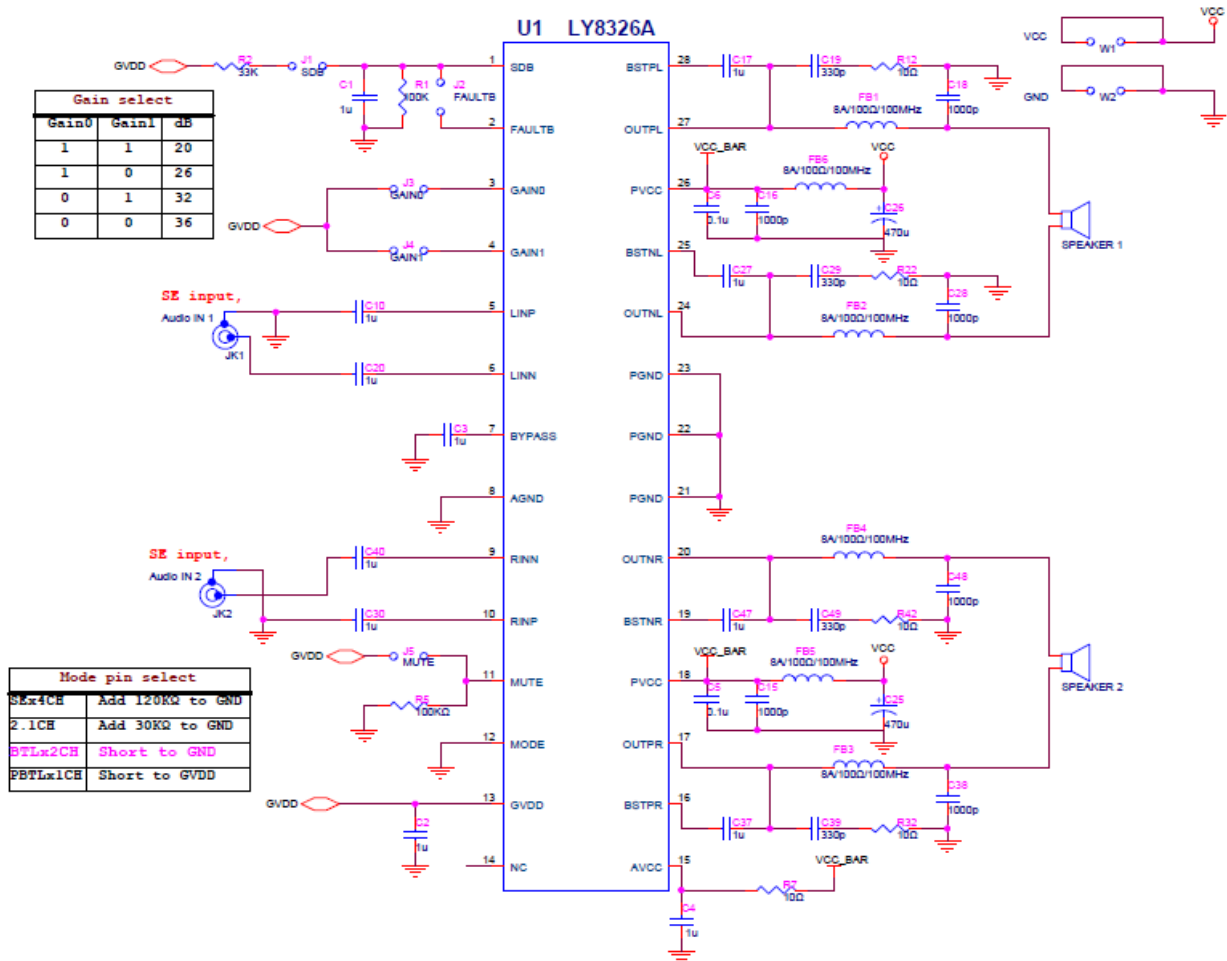


Figure 19 LY8326A Demo Board Application Circuit (BTLx2 mode)

Demo Board BOM List (BTLx2 mode)

LY8326A, BTLx2 V2.2 BOM List

No.	Part No.	Reference	QTY	Description	Note
1	IC, LY8326A	U1	1	CLASS-D Audio AMP, TSSOP28EP	
2	Capacitor, 470uF	C25, C26	2	35V, 105°C, 10*20, EC Cap.	
3	Capacitor, 0.1uF	C5, C6	2	SMD0805, CER, 80%/-20%	
4	Capacitor, 1uF	C1, C2, C3, C4, C10, C20, C30, C40 C17, C27, C37, C47	12	SMD0805, CER, 80%/-20%	
5	Capacitor, 1000pF	C15, C16, C18, C28, C38, C48	6	SMD0805, CER, 80%/-20%	
6	Capacitor, 330pF	C19, C29, C39, C49	4	SMD0805, CER, 80%/-20%	
7	Resistor, 100KΩ	R1, R5	2	SMD0805, 1/8W, 1%	
8	Resistor, 33KΩ	R2	1	SMD0805, 1/8W, 1%	
9	Resistor, 10Ω	R7, R12, R22, R32, R42	5	SMD0805, 1/8W, 1%	
10	Ferrite Bead	FB1, FB2, FB3, FB4, FB5, FB6	6	SMD1812, 8A/100Ω/100Mhz	

Demo Board Application Circuit (SEx4 mode)

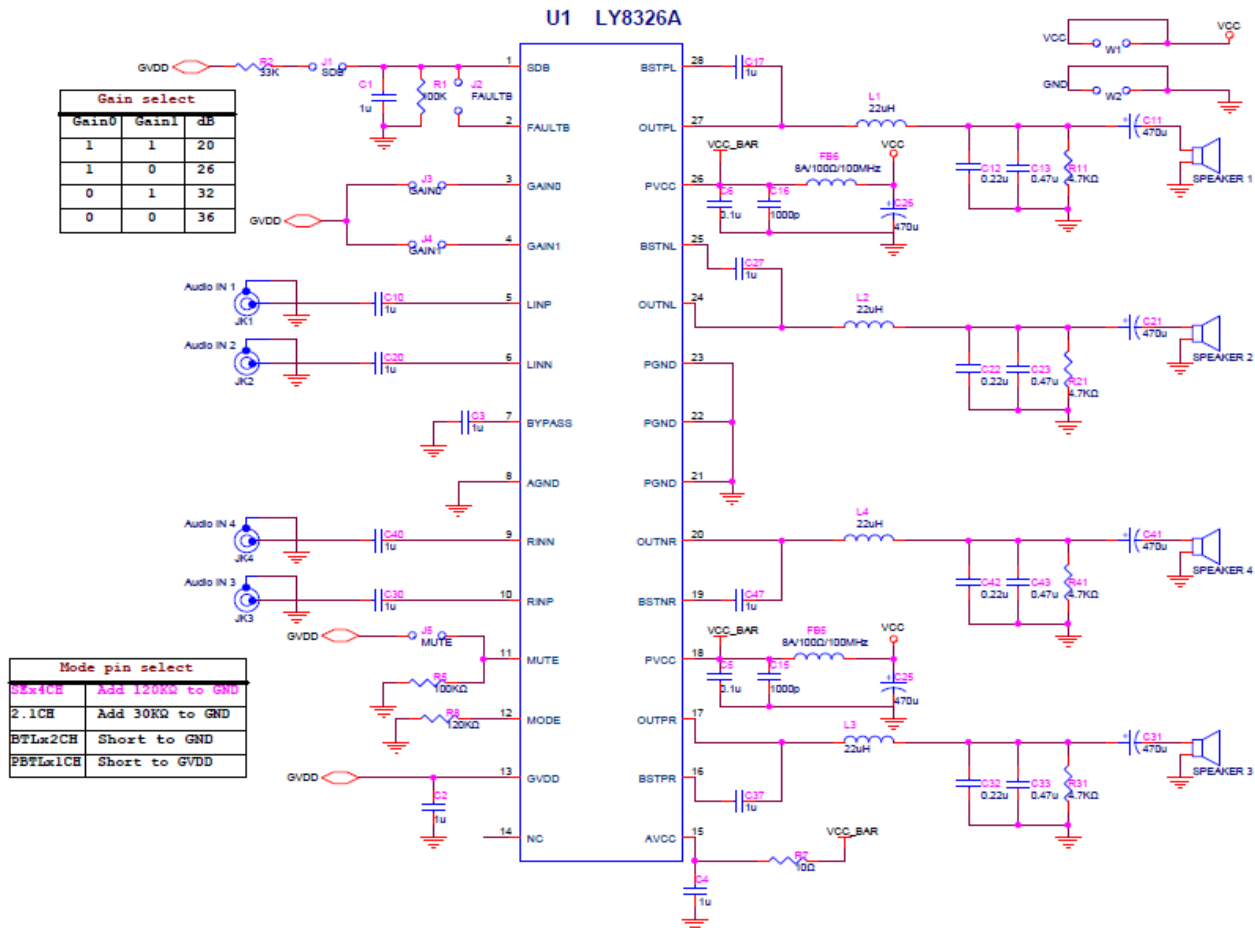


Figure 20 LY8326A Demo Board Application Circuit (SEx4 mode)

Demo Board BOM List (SEx4 mode)

LY8326A, SEx4 V2.2 BOM List

No.	Part No.	Reference	QTY	Description	Note
1	IC, LY8326A	U1	1	CLASS-D Audio AMP, TSSOP28EP	
2	Capacitor, 470uF	C25, C26, C11, C21, C31, C41	6	35V, 105°C, 10*20, EC Cap.	
3	Capacitor, 0.1uF	C5, C6	2	SMD0805, CER, 80%/-20%	
4	Capacitor, 0.22uF	C12, C22, C32, C42	4	SMD0805, CER, 80%/-20%	
5	Capacitor, 0.47uF	C13, C23, C33, C43	4	SMD0805, CER, 80%/-20%	
6	Capacitor, 1uF	C1, C2, C3, C4, C10, C20, C30, C40, C17, C27, C37, C47	12	SMD0805, CER, 80%/-20%	
7	Capacitor, 1000pF	C15, C16	2	SMD0805, CER, 80%/-20%	
8	Capacitor, 330pF	C19, C29, C39, C49	4	SMD0805, CER, 80%/-20%	
9	Resistor, 120KΩ	R8	1	SMD0805, 1/8W, 1%	
10	Resistor, 100KΩ	R1, R5	2	SMD0805, 1/8W, 1%	
11	Resistor, 4.7KΩ	R11, R21, R31, R41	4	SMD0805, 1/8W, 1%	
12	Resistor, 33KΩ	R2	1	SMD0805, 1/8W, 1%	
13	Resistor, 10Ω	R7	1	SMD0805, 1/8W, 1%	
14	Ferrite Bead	FB5, FB6	2	SMD1812, 8A/100Ω/100Mhz	
15	Fixed Inductors	L1, L2, L3, L4	4	DIP, 22uH, TOKO (A7502BY-220M)	

Demo Board Application Circuit (2.1CH mode)

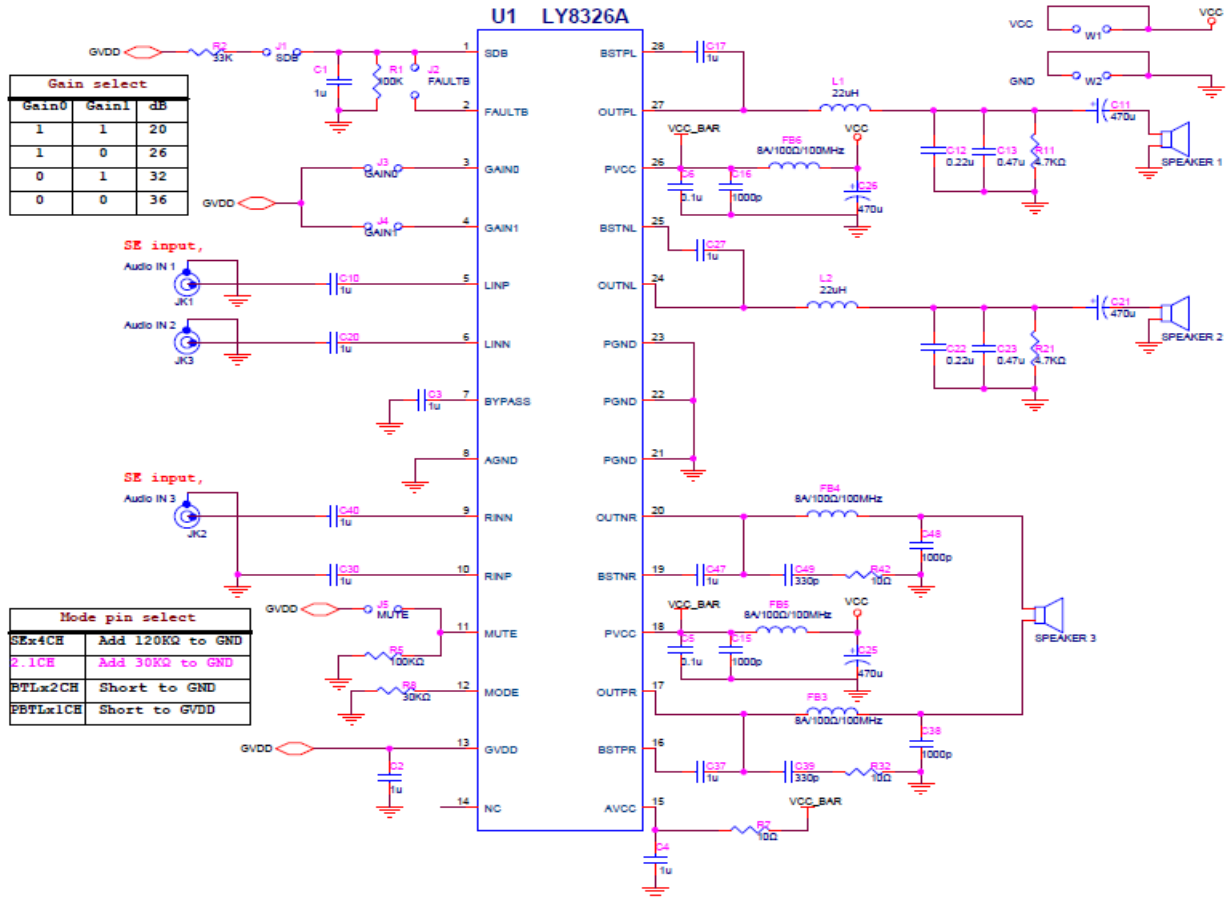


Figure 21 LY8326A Demo Board Application Circuit (2.1CH mode)

Demo Board BOM List (2.1CH mode)

LY8326A, 2.1CH V2.2 BOM List

No.	Part No.	Reference	QTY	Description	Note
1	IC, LY8326A	U1	1	CLASS-D Audio AMP, TSSOP28EP	
2	Capacitor, 470uF	C25, C26, C11, C21	4	35V, 105°C, 10*20, EC Cap.	
3	Capacitor, 0.1uF	C5, C6	2	SMD0805, CER, 80%/-20%	
4	Capacitor, 0.22uF	C12, C22	2	SMD0805, CER, 80%/-20%	
5	Capacitor, 0.47uF	C13, C23	2	SMD0805, CER, 80%/-20%	
6	Capacitor, 1uF	C1, C2, C3, C4, C10, C20, C30, C40 C17, C27, C37, C47	12	SMD0805, CER, 80%/-20%	
7	Capacitor, 1000pF	C15, C16, C38, C48	4	SMD0805, CER, 80%/-20%	
8	Capacitor, 330pF	C39, C49	2	SMD0805, CER, 80%/-20%	
9	Resistor, 10Ω	R7, R32, R42	3	SMD0805, 1/8W, 1%	
10	Resistor, 4.7KΩ	R11, R21	2	SMD0805, 1/8W, 1%	
11	Resistor, 30KΩ	R8	1	SMD0805, 1/8W, 1%	
12	Resistor, 33KΩ	R2	1	SMD0805, 1/8W, 1%	
13	Resistor, 100KΩ	R1, R5	2	SMD0805, 1/8W, 1%	
14	Ferrite Bead	FB3, FB4, FB5, FB6	4	SMD1812, 8A/100Ω/100Mhz	
15	Fixed Inductors	L1, L2	2	DIP, 22uH, TOKO (A7502BY-220M)	

Demo Board Application Circuit (PBTLx1 mode)

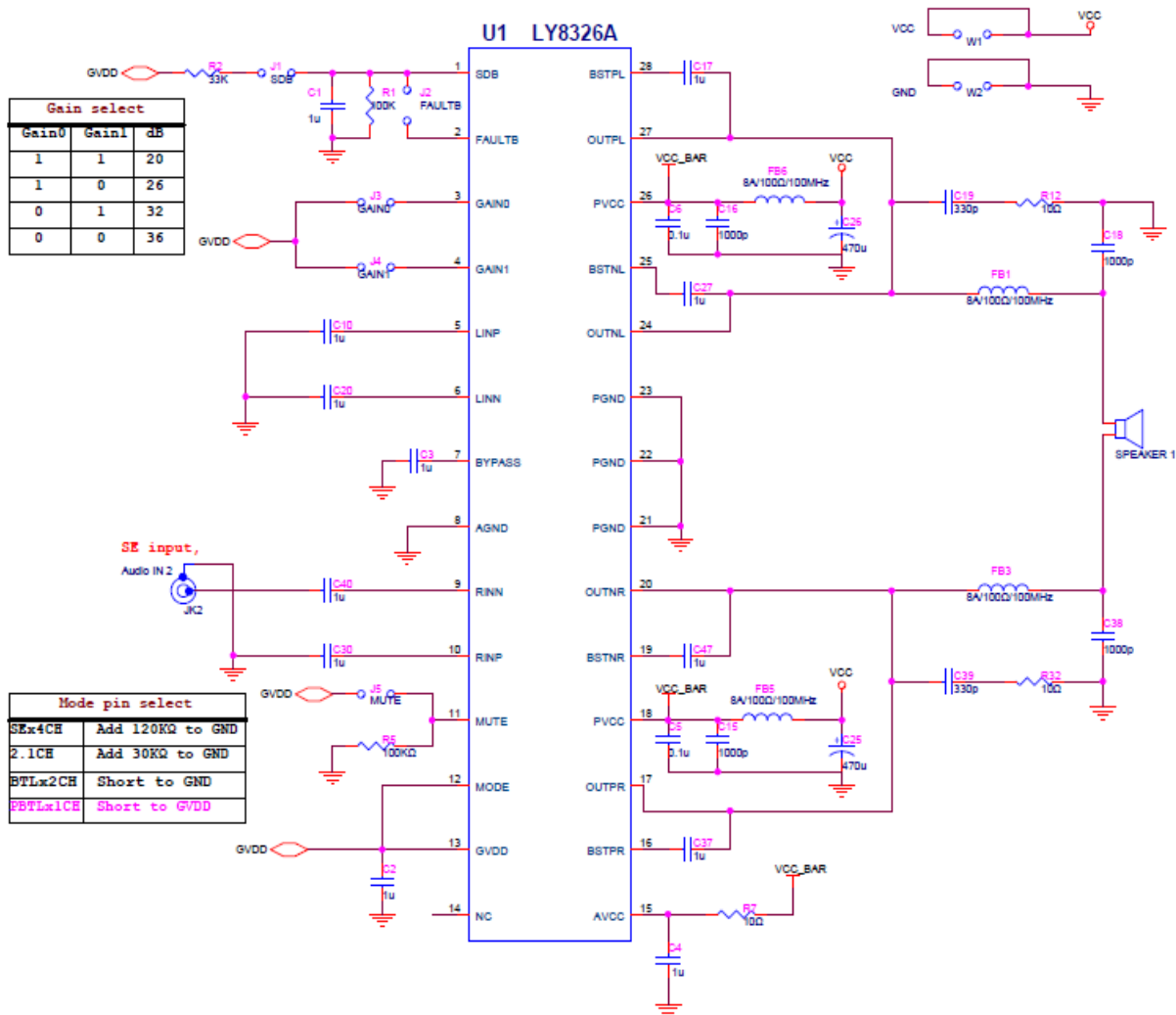
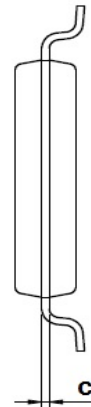
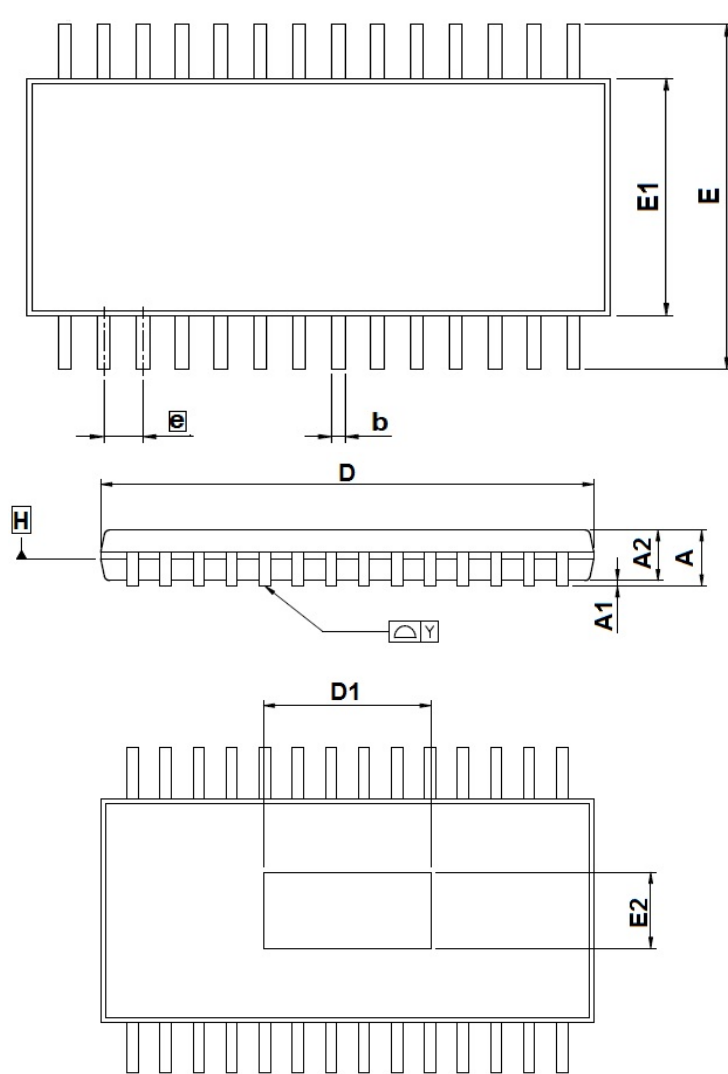


Figure 22 LY8326A Demo Board Application Circuit (PBTLx1 mode)

Demo Board BOM List (PBTLx1 mode)

LY8326A, PBTLx1 V2.2 BOM List

No.	Part No.	Reference	QTY	Description	Note
1	IC, LY8326A	U1	1	CLASS-D Audio AMP, TSSOP28EP	
2	Capacitor, 470uF	C25, C26	2	35V, 105°C, 10*20, EC Cap.	
3	Capacitor, 0.1uF	C5, C6	2	SMD0805, CER, 80%/-20%	
4	Capacitor, 1uF	C1, C2, C3, C4, C10, C20, C30, C40, C17, C27, C37, C47	12	SMD0805, CER, 80%/-20%	
5	Capacitor, 1000pF	C15, C16, C18, C38	4	SMD0805, CER, 80%/-20%	
6	Capacitor, 330pF	C19, C39	2	SMD0805, CER, 80%/-20%	
7	Resistor, 100KΩ	R1, R5	2	SMD0805, 1/8W, 1%	
8	Resistor, 33KΩ	R2	1	SMD0805, 1/8W, 1%	
9	Resistor, 10Ω	R7, R12, R32	3	SMD0805, 1/8W, 1%	
10	Ferrite Bead	FB1, FB3, FB5, FB6	4	SMD1812, 8A/100Ω/100Mhz	

PACKAGE OUTLINE DIMENSION
TSSOP 28 Pin Package Outline Dimension


VARIATIONS (ALL DIMENSIONS SHOWN IN MM)

SYMBOLS	MIN.	NOM.	MAX.
A	—	—	1.20
A1	0.00	—	0.15
A2	0.80	1.00	1.05
b	0.19	—	0.30
c	0.09	—	0.20
D	9.60	9.70	9.80
E1	4.30	4.40	4.50
E	6.40 BSC		
θ	0.65 BSC		
L1	1.00 REF		
L	0.45	0.60	0.75
S	0.20	—	—
θ	0°	—	8°
Y	0.10		

THERMALLY ENHANCED DIMENSIONS(SHOWN IN MM)

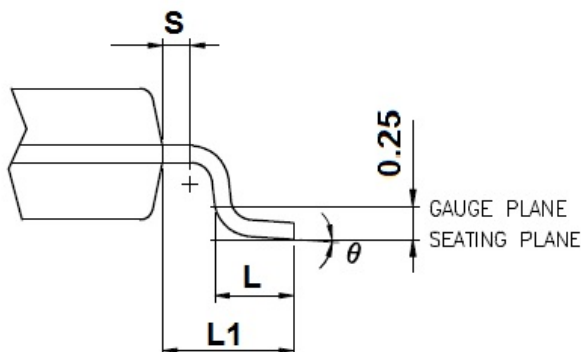
PAD SIZE	E2		D1	
	MIN.	MAX.	MIN.	MAX.
118X21*	2.40	3.15	4.41	5.66



*表示汎用字元,此汎用字元可能被其它不同字元所取代,实际的字元請参照bonding diagram所示.

"*" is an universal character, which means maybe replaced by specific character, the actual character please refers to the bonding diagram.

THERMALLY ENHANCED VARIATIONS ONLY



NOTES:

- JEDEC OUTLINE :
STANDARD : MO-153 AE REV.F
THERMALLY ENHANCED : MO-153 AET REV.F
- DIMENSION 'D' DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH, PROTRUSIONS OR GATE BURRS SHALL NOT EXCEED 0.15 PER SIDE.
- DIMENSION 'E1' DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 PER SIDE.
- DIMENSION 'b' DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 MM TOTAL IN EXCESS OF THE 'b' DIMENSION AT MAXIMUM MATERIAL CONDITION. DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OF THE FOOT. MINIMUM SPACE BETWEEN PROTRUSION AND ADJACENT LEAD IS 0.07 MM.
- DIMENSIONS 'D' AND 'E1' TO BE DETERMINED AT DATUM

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